

Resonant tunneling through ultrasmall quantum dots: zero-bias anomalies, magnetic field dependence, and boson-assisted transport

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We study resonant tunneling through a single-level quantum dot in the presence of strong Coulomb repulsion beyond the perturbative regime. The level is either spin-degenerate or can be split by a magnetic field. We, furthermore, discuss the influence of a bosonic environment. Using a real-time diagrammatic formulation we calculate transition rates, the spectral density and the nonlinear $I - V$ characteristic. The spectral density shows a multiplet of Kondo peaks split by the transport voltage and the boson frequencies, and shifted by the magnetic field. This leads to zero-bias anomalies in the differential conductance, which agree well with recent experimental results for the electron transport through single-charge traps. Furthermore, we predict that the sign of the zero-bias anomaly depends on the level position relative to the Fermi level of the leads.

I. INTRODUCTION

The experimental study of tunneling through zero-dimensional states in quantum dots with high charging energies has received recently considerable interest¹⁻⁷. Theoretical studies cover the classical regime (high temperatures)⁸⁻¹² as well as the quantum-mechanical regime (low temperatures)¹³⁻²³. In the latter case, Coulomb blockade and resonant-tunneling phenomena together with nonequilibrium generalizations of the Kondo effect are expected to occur. This leads to zero-bias anomalies in the differential conductance, which recently have been observed by Ralph & Buhrman²⁴. In this article, we present a new real-time diagrammatic approach to describe resonant tunneling at low temperatures and compare our results to the latter experiment.

The experiments for Coulomb blockade phenomena in zero-dimensional systems are usually performed in double-barrier resonant-tunneling structures^{2,3}, split-gate quantum-dot devices⁴⁻⁶, quantum point-contacts with single-charge trap states²⁴ and quite recently also in ultrasmall metallic tunnel junctions⁷ with Al particles of diameter below 10nm. In the latter experiment, the level spacing is of order $0.5meV$ which is comparable to the Coulomb charging energy in usual quantum dots. Therefore, the quantum dot is described by the nonequilibrium Anderson model where the energy level ϵ_σ (with spin label σ) is coupled via tunneling barriers to two electron reservoirs with different electrochemical potentials μ_L and μ_R . The charging energy is described by a strong on-site Coulomb repulsion U which suppresses double occupancy of the dot level. In equilibrium, it is well known from the theory of strongly correlated fermions²⁵ that the spectral density of the dot can exhibit a Kondo resonance at the Fermi level. It occurs for a low lying level $\epsilon_\sigma - \mu_{L,R} < -\Gamma$ and weak Zeeman splitting $|\epsilon_\sigma - \epsilon_{\bar{\sigma}}| < \Gamma$, where $\Gamma/2$ is the level width in the noninteracting case, and provided that temperature is lower than the Kondo temperature^{25,26} $T_K = 1/2(U\Gamma)^{1/2} \exp[\pi\epsilon(\epsilon + U)/(\Gamma U)]$. Since the weight of the equilibrium spectral density at the Fermi level is proportional to the linear conductance, an enhancement of the latter due to Kondo-assisted tunneling was predicted^{17,18}. Typical values for quantum dots are $U \sim 1meV$ and $\Gamma \sim 50\mu eV$ which, for $\epsilon \sim -\Gamma$, yield a Kondo temperature of the order $T_K \sim 50mK$. Due to heating effects such temperatures are still hard to realize in realistic dots. A more pronounced feature was found for the nonlinear conductance which shows a zero-bias maximum even for temperatures above the Kondo temperature^{13,14}. At zero magnetic field the spectral density of each spin channel exhibits a Kondo resonance at each of the chemical potentials. An applied magnetic field causes the Kondo peaks to shift from the chemical potential by the Zeeman energy, in opposite directions for the different spin channels. As a consequence, Kondo-assisted tunneling can only occur if the bias voltage exceeds the Zeeman energy. Therefore, the zero-bias anomaly is split by an applied magnetic field¹⁴. These features have been observed experimentally by Ralph & Buhrman²⁴. They measured the differential conductance through single-charge traps in a metallic quantum point-contact. Although this system does not allow a controlled variation of the level position, the appearance of a zero-bias maximum with a peak height varying logarithmically with temperature clearly demonstrates the mechanism of Kondo-assisted tunneling. However, the detailed comparison of the line shape in the experiment and the existing theory showed significant deviations.

In this paper, we will describe a new approach to calculate nonequilibrium properties of strongly correlated mesoscopic systems coupled to fermionic or bosonic baths via particle and energy exchange. It consists in a real-time diagrammatic approach closely related to path-integral methods formulated in connection with dissipation²⁷⁻²⁹ or tunneling in metallic junctions³¹⁻³³. One of the difficulties of the present problem lies in the fact that we have to account for the Coulomb interaction in a nonperturbative way. Therefore, the standard many-body diagrammatic

approaches are not sufficient (since Wick's theorem cannot be applied naively). We circumvent the problem by keeping track explicitly of the time evolution of the density matrix of the dot and tracing out only the bath degrees of freedom, which are assumed to be in equilibrium. The final diagrammatic language is set up by an expansion in the coupling to the fermionic reservoirs whereas the strong correlations on the local system are exactly taken into account. The basic step is the calculation of transition and current rates between different states of the dot. We present an exact expression for these rates as the sum over all irreducible diagrams. The transition rate is used to set up a formally exact Master equation from which the time-dependent probability distribution for the dot can be calculated. The current rate is generally not identical to the transition rate since it contains also the number of particles transferred to the reservoir where the current is calculated. This number can take arbitrary values if one considers all higher order processes. The occupation probabilities multiplied with the current rates are used to calculate the current flowing through the system. In earlier publications, we have presented this technique in connection with tunneling through a metallic island with a continuum of states³⁴ and demonstrated the equivalence to path-integral methods³⁵. There we used an approximation for the rate to sum up "inelastic resonant tunneling" processes to arbitrary order where different electrons tunnel coherently back and forth between the island and the reservoirs. Here, we apply an equivalent approximation to describe resonant tunneling between metallic leads through an ultrasmall quantum dot with a single level. An important advantage of our approach is that we can solve the noninteracting limit exactly and can control systematically if this limit is contained within a given approximation for the correlated case. The theory is current conserving and can be used for the calculation of correlation functions or Green's functions as well.

For the case where the dot level is M -fold degenerate we recover for $M \geq 2$ and a low lying dot level a Kondo peak in the spectral function. An applied transport voltage leads to a splitting of the Kondo peak (at μ_α where α denotes the lead), which results in a zero-bias anomaly in the differential conductance, such that the conductance has a maximum at $V = 0$. On the other hand, if the dot level lies above the Fermi levels of the leads μ_α we predict¹⁵ a zero-bias anomaly in the conductance which has a minimum at $V = 0$.

Several extensions will be considered. We study the case where the (spin-) degeneracy of the dot level is lifted, e.g., by an applied magnetic field. In this case the Kondo peaks of both spin channels move apart from each other by the level spacing $\epsilon_\sigma - \epsilon_{\bar{\sigma}}$, and Kondo-assisted tunneling sets in only at transport voltages eV exceeding this splitting. The calculated conductance agrees well with the experimental results of Ref. 24.

We, furthermore, account for inelastic interactions with bosonic modes coupled to the dot. They describe applied time-dependent fields, interaction with phonons, or the fluctuations in the electrodynamic environment. The investigation of this field has started only recently in connection with transport through interacting quantum dots. The classical regime ($\Gamma \gg T$) has been analyzed for time-dependent fields¹¹ and bosonic environments³⁶. Photon- and boson-assisted tunneling leads here to resonant side peaks in the Coulomb oscillations which can be used to analyze the complete excitation spectrum of the dot. The results agree well with experiments³⁷. In the Kondo regime it has been found²² that time-dependent perturbations split the Kondo resonances which leads to satellite anomalies in the differential conductance and offers the possibility to realize pump effects which are purely based on the presence of Kondo resonances. The linear AC-conductance has been analyzed in Ref. 38. In this paper, we will investigate the influence of an external bosonic field on transport phenomena through ultrasmall quantum dots at low temperatures and small boson frequencies (compared to Γ). The emission and absorption of bosons causes additional Kondo singularities, for a one-mode field at $\mu_\alpha + n\omega_B$, where $n = \pm 1, \pm 2, \dots$. Again, these resonances lead to corresponding anomalies in the differential conductance, which are inverted if the level position of the dot is moved through the Fermi energy.

II. HAMILTONIAN

We concentrate here on a dot containing only one energy level $\epsilon_\sigma^{(0)}$ with degeneracy M . In a magnetic field, due to the Zeeman energy the level position is spin dependent. The dot is connected via high tunneling barriers to two large noninteracting reservoirs and coupled capacitively to an external gate voltage. The model Hamiltonian of this "single-electron transistor" (see Fig. 1) is

$$H = H_0 + H_T = H_D + \sum_{\alpha=L,R} H_\alpha + H_T. \quad (1)$$

Here, H_D is the Hamiltonian for the dot. It includes the Coulomb interaction of the dot electrons, which is described within the capacitance model of a single-electron transistor by the capacitances C_L and C_R for the left and right tunnel junction and C_G for the gate. Furthermore, the dot electrons are coupled to bosonic modes ω_q with electron-boson coupling g_q . Thus, H_D reads

$$H_D = \sum_{\sigma} \epsilon_{\sigma}^{(0)} n_{\sigma} + E_C \left(\hat{N} - n_G \right)^2 + \sum_q \omega_q d_q^{\dagger} d_q + \hat{N} \sum_q g_q (d_q + d_q^{\dagger}). \quad (2)$$

(Throughout this work, we set $\hbar = k = 1$ and use the convention $e > 0$.) The particle number on the dot with spin σ is $n_{\sigma} = c_{\sigma}^{\dagger} c_{\sigma}$, and $\hat{N} = \sum_{\sigma} n_{\sigma}$. The scale of the charging energy is provided by $E_C \equiv e^2/2C$, where $C = C_L + C_R + C_G$ is the total capacitance of the system. The transistor can be tuned by the gate voltage V_G via $e n_G = C_L V_L + C_R V_R + C_G V_G$. We remark here, that H is invariant under a global shift of all energies. Therefore, we can always choose symmetric bias, $V_L = -V_R = V/2$.

The next term in Eq. (1), $H_{\alpha} = \sum_{k\sigma} \epsilon_{k\alpha} a_{k\sigma\alpha}^{\dagger} a_{k\sigma\alpha}$, describes the reservoir α of noninteracting electrons in the leads. Finally, the dot is coupled via tunnel barriers to the left and right lead. This coupling is described by the tunnel Hamiltonian

$$H_T = \sum_{k\sigma\alpha} (T_k^{\alpha} a_{k\sigma\alpha}^{\dagger} c_{\sigma} + h.c.). \quad (3)$$

The bosonic modes can represent interaction with phonons^{39–41} or fluctuations of the electrodynamic environment^{42–45} very similar to the Caldeira-Leggett model⁴⁶. For our theory no assumption is needed for the specific kind of the modes ω_q and the couplings g_q . In this way we are able to present a general result for the current which shows the influence of inelastic interactions for an arbitrary environment.

The capacitive model is equivalent to the Anderson Hamiltonian, which we obtain by defining the interaction $U_0 = 2E_C$ and shifting the level position $\epsilon_{\sigma}^{(0)} + 2E_C - eV_G C_G/C - a_c eV/2 \rightarrow \epsilon_{\sigma}^{(0)}(V, V_G)$. The asymmetry factor $a_c = (C_L - C_R)/C$ accounts for a different capacitive coupling of the left and right lead. We see here, that the effective level position in the Anderson model depends on the gate voltage, as well as, due to a_c , on the transport voltage. The dot is then described by

$$H_D = \sum_{\sigma} \epsilon_{\sigma}^{(0)}(V, V_G) n_{\sigma} + U_0 \sum_{\sigma < \sigma'} n_{\sigma} n_{\sigma'} + \sum_q \omega_q d_q^{\dagger} d_q + \hat{N} \sum_q g_q (d_q + d_q^{\dagger}). \quad (4)$$

An unitary transformation⁴⁷ with $V = \exp(-i\hat{N}\varphi)$ and $\varphi = i \sum_q (g_q/\omega_q)(d_q^{\dagger} - d_q)$ yields $\bar{H} = V H V^{-1} = \bar{H}_0 + \bar{H}_T$, where $\bar{H}_0 = H_R + \bar{H}_D$,

$$\bar{H}_D = \sum_{\sigma} \epsilon_{\sigma} n_{\sigma} + U \sum_{\sigma < \sigma'} n_{\sigma} n_{\sigma'} + \sum_q \omega_q d_q^{\dagger} d_q \quad (5)$$

and

$$\bar{H}_T = \sum_{k\sigma\alpha} (T_k^{\alpha} a_{k\sigma\alpha}^{\dagger} c_{\sigma} e^{i\varphi} + h.c.). \quad (6)$$

The electron-boson interaction renormalizes the level position and the Coulomb repulsion, $\epsilon_{\sigma} = \epsilon_{\sigma}^{(0)} - \sum_q g_q^2/\omega_q$ and $U = U_0 - 2 \sum_q g_q^2/\omega_q$, and the tunneling term acquires phase factors $e^{\pm i\varphi}$.

For strong Coulomb repulsion U we restrict ourselves to states with $N = 0, 1$. In lowest order perturbation theory the rates for tunneling in and out of the dot to reservoir α are

$$2\pi\gamma_{\alpha}^{\pm}(E) = 2\pi \int dE' \bar{\gamma}_{\alpha}^{\pm}(E') P^{\pm}(E - E'), \quad (7)$$

where $2\pi\bar{\gamma}_{\alpha}^{\pm}(E) = \Gamma_{\alpha}(E) f_{\alpha}^{\pm}(E)$ is the classical rate without bosons, $\Gamma_{\alpha}(E) = 2\pi \sum_k |T_k^{\alpha}|^2 \delta(E - \epsilon_{k\alpha})$, and $f_{\alpha}^{+}(E)$ is the Fermi distribution of reservoir α with electrochemical potential μ_{α} , while $f_{\alpha}^{-}(E) = 1 - f_{\alpha}^{+}(E)$. Finally,

$$P^{\pm}(E) = \frac{1}{2\pi} \int dt e^{iEt} \langle e^{i\varphi(0)} e^{-i\varphi(\pm t)} \rangle_0 \quad (8)$$

describes the probability that an electron absorbs (P^{+}) or emits (P^{-}) the boson energy E .^{42–44} The expectation value is taken with the free boson Hamiltonian. These probabilities satisfy the condition of detailed balance⁴⁸

$$P^{-}(E) = P^{+}(-E) = e^{\beta E} P^{+}(E) \quad (9)$$

The classical rates combined with a master equation are sufficient in the perturbative regime $\Gamma = \sum_{\alpha} \Gamma_{\alpha} \ll T$.³⁶

In order to go beyond the perturbative regime, we need a nonperturbative treatment of the tunneling, where quantum fluctuations yield finite life-time broadening and renormalization effects of the dot levels. As an illustration we first assume that (for $B = 0$) the broadening is given by the sum of the classical transition rates, Eq. (7). Using Kramers-Kronig we deduce the renormalization and obtain for the self-energy

$$\sigma(E) = \int dE' \frac{M\gamma^+(E') + \gamma^-(E')}{E - E' + i0^+}. \quad (10)$$

where $\gamma^\pm = \sum_\alpha \gamma_\alpha^\pm$. The aim of the present letter is to test and extend this simple physical picture within a systematic and conserving theory for all Green's functions and the current. To achieve this we use a real-time technique developed in Ref. 34,35,15 which provides a natural generalization of the classical and cotunneling theory to the physics of resonant tunneling.

III. DIAGRAMMATIC TECHNIQUE

A quantum-statistical expectation value of an operator A at time t is given by

$$\langle A(t) \rangle = \text{tr}[\rho_0 A(t)_{\bar{H}}], \quad (11)$$

where $A(t)_{\bar{H}} = \exp[i\bar{H}(t - t_0)]A \exp[-i\bar{H}(t - t_0)]$ is the operator in Heisenberg picture with respect to the initial time t_0 . Permutation under the trace yields $\langle A(t) \rangle = \text{tr}[\rho(t)A]$ with A in Schrödinger picture. The density matrix $\rho(t)$ evolves in time via $\rho(t) = e^{-i\bar{H}(t-t_0)}\rho(t_0)e^{i\bar{H}(t-t_0)}$. We assume that the initial density matrix $\rho_0 = \rho(t_0)$ factorizes into parts for the dot electrons, the bosons, and the leads:

$$\rho_0 = \rho_0^D \rho_0^B \prod_\alpha \rho_0^\alpha. \quad (12)$$

The leads are treated as large equilibrium reservoirs with fixed electrochemical potentials $\mu_\alpha = -eV_\alpha$. Therefore, we describe the electrons in the leads by Fermi functions $f_\alpha(E)$ and the density matrix reads

$$\rho_0^\alpha = \frac{1}{Z_0^\alpha} \exp[-\beta(H_\alpha - \mu_\alpha N_\alpha)] \quad (13)$$

where $\beta = 1/T$ and $N_\alpha = \sum_{k\sigma} a_{k\sigma\alpha}^\dagger a_{k\sigma\alpha}$ the number of electrons in the lead α . The normalization factor Z_0^α is determined by $\text{tr} \rho_0^\alpha = 1$. The boson part reads

$$\rho_0^B = \frac{1}{Z_0^B} \exp \left[-\beta_B \sum_q \omega_q d_q^\dagger d_q \right]. \quad (14)$$

The temperature of the boson bath, $T_B = 1/\beta_B$, may differ in real experiments from the electron temperature T .

For the initial distribution of the dot we assume that it is diagonal in the many-body *dot* states, $|\chi\rangle$, which include the strong correlations within the quantum dot but are assumed to have fixed occupation numbers,

$$\rho_0^D = \sum_\chi P_\chi^0 |\chi\rangle \langle \chi|, \quad (15)$$

with $\sum_\chi P_\chi^0 = 1$. We will see later, that in the stationary limit, i.e., when t_0 is shifted to minus infinity, all the physical quantities are independent of the choice of P_χ^0 .

In the following, it is convenient to change to the interaction picture with respect to $\bar{H}_0$. This implies $A(t)_{\bar{H}} = \tilde{T} \exp \left(-i \int_{t_0}^t dt' \bar{H}_T(t')_I \right) A(t)_I T \exp \left(-i \int_{t_0}^t dt' \bar{H}_T(t')_I \right)$ in which T is the time-ordering and $\tilde{T}$ denotes the anti-time-ordering operator. We write the integrals as one contour integral $\int_K dt' \dots$ over the *Keldysh contour*. It is parameterized by the “time” t' which first runs forward from t_0 to t and then backward from t to t_0 . In the diagrammatic language, the Keldysh contour is represented by horizontal lines running from the left to the right and then back to the left (see Fig. 2). We find

$$\langle A(t) \rangle = \text{tr} \left[\rho_0 T_K \exp \left(-i \int_K dt' \bar{H}_T(t')_I \right) A(t)_I \right]. \quad (16)$$

Here, we have introduced the Keldysh time-ordering operator T_K , which orders all following operators along the Keldysh contour such that the one with the later “time” along the Keldysh contour appears at a more left position (without any sign change for an exchange of Fermi operators).

In the following we will encounter also higher order correlation functions of the type $\langle T_K A_1(t_1)_I A_2(t_2)_I \dots A_n(t_n)_I \rangle$. The final time t of the Keldysh contour is then given by $\max\{t_1, \dots, t_n\}$.

For a diagrammatic description we expand the exponential with respect to the tunneling Hamiltonian and obtain

$$\langle T_K \prod_{i=1}^n A_i(t_i) \rangle = \text{tr} \left[\rho_0 \sum_{m=0}^{\infty} (-i)^m \int_K dt'_1 \int_K dt'_2 \dots \int_K dt'_m T_K \left\{ \bar{H}_T(t'_1)_I \bar{H}_T(t'_2)_I \dots \bar{H}_T(t'_m)_I \prod_{i=1}^n A_i(t_i)_I \right\} \right] \quad (17)$$

$t'_1 > t'_2 > \dots > t'_m$

in which the relation $t'_1 > t'_2 > \dots > t'_m$ has to be understood with respect to the Keldysh contour. The time-ordering operator T_K acts also on the operators $A_i(t_i)_I$ and puts them on the right place between the tunneling Hamiltonians.

The next task is to perform the trace of each term of the expansion. We insert the tunnel Hamiltonian (6) and notice that the Hamiltonian $\bar{H}_0$ is bilinear in the lead electron operators. For this reason, Wick’s theorem holds for these degrees of freedom, i.e., the lead electron operators are contracted in pairs. This includes contractions between pairs of field operators from $\bar{H}_T$ as well as contractions to lead electron operators which can be present in the operators A_i . These contractions are given by equilibrium distribution functions. For the dot electrons, the situation is different. The Coulomb interaction is expressed by a quartic term of dot electron operators. Therefore, Wick’s theorem does not hold for this part of the system. A product of dot electron operators can not be contracted into pairs, but has to be treated explicitly. The trace over the bosonic part, however, poses no problem. Each tunneling term contains an exponential $e^{\pm i\varphi}$ of the bosonic operators φ . The trace over the product of such exponentials can be performed easily (see Eq. (20)) provided that the operator A also contains only such exponentials.

A. The rules

With regard to the applications discussed in section III B and III C, we assume here that the operators A_i (representing “external vertices”) depend on the lead and boson degrees of freedom only in the form

$$A_i = A_i \left(\sum_k T_k^\alpha a_{k\sigma\alpha}^\dagger c_\sigma e^{i\varphi}, \sum_k T_k^{\alpha*} c_\sigma^\dagger a_{k\sigma\alpha} e^{-i\varphi}, c_\sigma e^{i\varphi}, c_\sigma^\dagger e^{-i\varphi} \right). \quad (18)$$

Each term of the expansion Eq. (17) is visualized by a diagram (see Fig. 2). There is a forward and a backward propagator symbolized by the upper and lower horizontal line, running from t_0 to t and back from t to t_0 , respectively. Along this time path, we arrange internal and external vertices according to their time-ordering. The internal vertices emerge from the insertion of the tunneling Hamiltonian (6) into the expansion (17). Each of them corresponds to a product of a lead and a dot electron operator and a phase factor $e^{\pm i\varphi}$. After integrating out the lead degrees of freedom, all vertices (either internal or external) containing a lead electron operator are connected in pairs by directed tunneling lines (dashed lines) $\bar{\gamma}_\alpha^K(t, t')$ from t' to t , with $\bar{\gamma}_\alpha^K(t, t') = \bar{\gamma}_\alpha^+(t - t')$ for $t < t'$ and $\bar{\gamma}_\alpha^K(t, t') = \bar{\gamma}_\alpha^-(t - t')$ for $t > t'$ with respect to the Keldysh contour with $\bar{\gamma}_\alpha^\pm(t) = \int dE e^{-iEt} \bar{\gamma}_\alpha^\pm(E)$. These tunneling lines represent contractions of lead electron operators.

There are vertices from which a tunneling line leaves (representing $a_{k\sigma\alpha}^\dagger(t) c_\sigma(t) e^{i\varphi(t)}$ which removes a dot electron with spin σ) and others to which a tunneling line enters (visualizing $c_\sigma^\dagger(t) a_{k\sigma\alpha}(t) e^{-i\varphi(t)}$ which adds a dot electron with spin σ). Fermi statistics, furthermore, yield a minus sign for each crossing of tunneling lines.

In the interaction picture the dot electron operators get exponential factors which contain the energies ϵ_χ of the many-body dot states χ given by $\epsilon_\chi |\chi\rangle = \bar{H}_D |\chi\rangle$. The order of the electron operators may induce furthermore a minus sign due to Fermi statistics.

The trace over the boson operators gives rise to a factor of the form

$$C_B(t_1, t_2, \dots, t_m, t'_1, t'_2, \dots, t'_m) = \langle T_K \left[e^{-i\varphi(t_1)} e^{-i\varphi(t_2)} \dots e^{-i\varphi(t_m)} e^{i\varphi(t'_1)} e^{i\varphi(t'_2)} \dots e^{i\varphi(t'_m)} \right] \rangle \quad (19)$$

Since φ is linear in the boson operators, we get

$$C_B(t_1, t_2, \dots, t_m, t'_1, t'_2, \dots, t'_m) = \prod_{i < j} P^K(t_i, t_j)^{-1} \prod_{i < j} P^K(t'_i, t'_j)^{-1} \prod_{i, j} P^K(t_i, t'_j). \quad (20)$$

We write $P^K(t, t') = P^+(t, t')$ for $t < t'$ and $P^K(t, t') = P^-(t, t')$ for $t > t'$ on the Keldysh contour with $P^\pm(t) = \int dE e^{-iEt} P^\pm(E)$. In the diagrammatic language, we represent the factors P^K by boson lines connecting each vertex with each other.

A summary of these rules are given in Appendix A.

In order to calculate stationary transport properties it is convenient to change to an energy representation. Without loss of generality we assume that the times $t_1, \dots, t_n$ of the correlation function (17) are ordered on the real axis according to $t_n < t_{n-1} < \dots < t_1 = t$. This may be different to the ordering on the Keldysh contour which depends on whether the times lie on the upper or lower branch. In the stationary limit we can set $t_0 = -\infty$ and $t = t_1 = 0$.

We consider the Laplace transform

$$G(E_2, E_3, \dots, E_n) = (-i)^{n-1} \int_{-\infty}^0 dt_2 \int_{-\infty}^{t_2} dt_3 \dots \int_{-\infty}^{t_{n-1}} dt_n e^{iE_2 t_2} e^{iE_3 t_3} \dots e^{iE_n t_n} \langle T_K A_1(0) A_2(t_2) \dots A_n(t_n) \rangle. \quad (21)$$

We will account for the exponential factors $\exp(iE_i t_i)$ ($i = 2, \dots, n$) by drawing directed virtual lines from the external vertices with time t_i to the last vertex with time $t_1 = 0$ and assigning the energy E_i to this virtual line.

Performing the time integrals we end up with diagrammatic rules in energy representation. These rules are summarized in Appendix B.

B. Master equation and stationary probabilities

In this section we will derive a formally exact expression for the central object of this paper: the quantum-mechanical transition rate $\Sigma_{\chi', \chi}(t', t)$ for the reduced system (the dot) to go from a state χ' at time t' to a state χ at time t . This rate will serve as an input for a formally exact and time-dependent Master equation which, in principle, could be used to calculate all occupation probabilities of the dot as a function of time for an arbitrary initial state. Similar Master equations are well-known and successfully applied in connection with macroscopic quantum coherence phenomena in spin bose models^{28–30}. The connection to these path-integral approaches will be described in Ref. 58.

A matrix element of the reduced density matrix of the dot at time t , $P_{\chi_2}^{\chi_1}(t)$, is given by the quantum-statistical expectation value of the projector $(|\chi_2\rangle\langle\chi_1|)(t)$

$$P_{\chi_2}^{\chi_1}(t) = \langle (|\chi_2\rangle\langle\chi_1|)(t) \rangle, \quad (22)$$

i.e., we have to set $n = 1$ and $A_1 = |\chi_2\rangle\langle\chi_1|$ in Eq. (17). The reduced density matrix commutes with the particle number on the dot. Thus, the operator $|\chi_2\rangle\langle\chi_1|$ is unaffected by the unitary transformation and no tunneling and boson line emerges from this external vertex. The matrix element $P_{\chi_2}^{\chi_1}(t)$ can be expressed by the reduced propagator $\Pi_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t)$ from χ_1' at time t' forward to χ_1 at time t and then from χ_2 at time t backward to χ_2' at time t'

$$P_{\chi_2}^{\chi_1}(t) = \sum_{\chi_1', \chi_2'} P_{\chi_2'}^{\chi_1'}(t') \Pi_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t). \quad (23)$$

The propagator is the sum of all diagrams with the given states at the ends and can be expressed by an irreducible self-energy part $\Sigma_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t)$, defined as the sum of all diagrams in which any vertical line cutting through them crosses at least one tunneling or boson line. The propagators for the four lines attached to the self-energy are not included in $\Sigma_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t)$. We obtain an iteration in the style of a Dyson equation (see Fig. 3),

$$\Pi_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t) = \Pi_{\chi_2}^{(0)\chi_1}(t', t) \delta_{\chi_1, \chi_1'} \delta_{\chi_2, \chi_2'} + \sum_{\chi_1'', \chi_2''} \int_{t'}^t dt_2 \int_{t'}^{t_2} dt_1 \Pi_{\chi_2'', \chi_2'}^{\chi_1', \chi_1''}(t', t_1) \Sigma_{\chi_2'', \chi_2}^{\chi_1'', \chi_1}(t_1, t_2) \Pi_{\chi_2}^{(0)\chi_1}(t_2, t), \quad (24)$$

where $\Pi_{\chi_2}^{(0)\chi_1}(t', t) = \exp[-i(\epsilon_{\chi_1} - \epsilon_{\chi_2})(t - t')]$ is the propagator of the isolated quantum dot. Multiplying this equation with $P_{\chi_2}^{\chi_1'}(t')$, summing over the states χ_1', χ_2' and differentiating with respect to t , we obtain together with Eq. (23) and setting $t' = t_0$

$$\frac{d}{dt} P_{\chi_2}^{\chi_1}(t) + i(\epsilon_{\chi_1} - \epsilon_{\chi_2}) P_{\chi_2}^{\chi_1}(t) = \sum_{\chi_1', \chi_2'} \int_{t_0}^t dt' P_{\chi_2'}^{\chi_1'}(t') \Sigma_{\chi_2', \chi_2}^{\chi_1', \chi_1}(t', t). \quad (25)$$

This formally exact equation is the most general kinetic equation for the reduced density matrix of the dot. No assumption is necessary for the initial state and the integral kernel Σ on the r.h.s. shows that memory effects are fully taken into account.

The equation simplifies considerably if we assume that the initial density matrix is diagonal. In the general case, this does not imply that the reduced density matrix stays diagonal for all times. However, for the special case of the Anderson model considered here, spin conservation implies that the reduced density matrix will be diagonal for all times $t > t_0$. Hence, we consider $\Sigma_{\chi',\chi} \equiv \Sigma_{\chi',\chi}^{\chi',\chi}$ and obtain from (25)

$$\frac{d}{dt}P_\chi(t) = \sum_{\chi'} \int_{t_0}^t dt' P_{\chi'}(t') \Sigma_{\chi',\chi}(t', t), \quad (26)$$

where $P_\chi(t) \equiv P_\chi^\chi(t)$ denotes the probability to be in the state χ at time t . For a time-translational invariant system, the time-dependent rates $\Sigma_{\chi',\chi}(t', t)$ depend only on the time difference $\Sigma_{\chi',\chi}(t' - t)$. Performing the Laplace transform of Eq. (26) one can then study the time evolution of arbitrary initial probability distributions into the stationary state.

By attaching the rightmost vertex of each diagram Σ to the upper and lower propagator the minus sign for each vertex on the backward propagator yields $\sum_\chi \Sigma_{\chi',\chi}(t', t) = 0$, which allows us to rewrite Eq. (26) in the form

$$\frac{d}{dt}P_\chi(t) = \sum_{\chi' \neq \chi} \int_{t_0}^t dt' [P_{\chi'}(t') \Sigma_{\chi',\chi}(t', t) - P_\chi(t') \Sigma_{\chi,\chi'}(t', t)], \quad (27)$$

We obtain the structure of a master equation with transition rates given by $\Sigma_{\chi',\chi}(t', t)$.

The stationary distribution is given by

$$P_\chi^{st} = \lim_{t \rightarrow \infty} P_\chi(t) = \lim_{t_0 \rightarrow -\infty} P_\chi(0) \quad (28)$$

and is *not* the equilibrium one if the electrochemical potentials of the leads are different. From (26) and (27) we obtain

$$0 = \sum_{\chi'} P_{\chi'}^{st} \Sigma_{\chi',\chi} = \sum_{\chi' \neq \chi} [P_{\chi'}^{st} \Sigma_{\chi',\chi} - P_\chi^{st} \Sigma_{\chi,\chi'}], \quad (29)$$

where

$$\Sigma_{\chi',\chi} = i \int_{-\infty}^0 dt' \Sigma_{\chi',\chi}(t', 0) \quad (30)$$

can be calculated directly by using our diagrammatic rules in energy space. The prefactor i in (30) together with the $m - 1$ time integrations over the internal vertices in Σ gives a factor i^m in (B1) which cancels the factor $(-i)^m$ from rule 5.

The self-energy part $\Sigma_{\chi',\chi}$ is purely imaginary. This can be seen by changing the vertical positions of all vertices on the Keldysh contour (without changing their horizontal position) and reversing the direction of all tunneling and boson lines. Consequently, only the energy differences ΔE_j from rule 2' will change sign. Since the number of vertices is even (all tunneling vertices are coupled in pairs by tunneling lines), there is no sign change due to rule 5' and the number of resolvents is odd. Thus, the whole diagram has been changed to its conjugate complex up to a sign.

C. The tunneling current

The tunneling current flowing into reservoir α is defined by $I_\alpha(t) = e \frac{d}{dt} \langle N_\alpha(t) \rangle = ie \langle [\bar{H}, N_\alpha](t) \rangle$, which is equivalent to

$$I_\alpha(t) = -ie \sum_{k\sigma} \left\{ T_k^\alpha \langle (a_{k\sigma\alpha}^\dagger c_\sigma e^{i\varphi})(t) \rangle - T_k^{\alpha*} \langle (c_\sigma^\dagger a_{k\sigma\alpha} e^{-i\varphi})(t) \rangle \right\}. \quad (31)$$

The tunneling current is an expectation value of a product of a dot, boson and reservoir electron operator (see Fig. 4). We obtain

$$I_\alpha(t) = e \sum_{\chi, \chi'} \int_{t_0}^t dt' P_{\chi'}(t') \Sigma_{\chi', \chi}^{\alpha+}(t', t) = -e \sum_{\chi, \chi'} \int_{t_0}^t dt' P_{\chi'}(t') \Sigma_{\chi', \chi}^{\alpha-}(t', t) \quad (32)$$

where the partial self-energies $\Sigma_{\chi', \chi}^{\alpha\pm}(t', t)$ are parts of the total self-energy

$$\Sigma_{\chi', \chi}(t', t) = \sum_{\alpha} \left\{ \Sigma_{\chi', \chi}^{\alpha+}(t', t) + \Sigma_{\chi', \chi}^{\alpha-}(t', t) \right\}. \quad (33)$$

They describe processes in which the rightmost tunneling line corresponds to reservoir α and is an outgoing (incoming) line if the rightmost vertex lies on the upper propagator or an incoming (outgoing) line if the rightmost vertex lies on the lower propagator. Their physical meaning is displayed by the current formula (32) which shows that they give the total contribution to the current rate. We can relate them to an intuitively more physical object, namely the rate $\Sigma_{\chi', \chi}^{\alpha p}(t', t)$, $p = 0, \pm 1, \pm 2, \dots$, which describes the transition rate where p particles are transferred to reservoir α . Within our graphical language $\Sigma_{\chi', \chi}^{\alpha p}(t', t)$ is given by all diagrams where the number of tunneling lines with reservoir index α running from the forward to the backward propagator minus the number of tunneling lines with reservoir index α running from the backward to the forward propagator is given by p . We obtain

$$\sum_{\chi} \Sigma_{\chi', \chi}^{\alpha\pm}(t', t) = \pm \sum_{\chi} \sum_p p \Sigma_{\chi', \chi}^{\alpha p}(t', t). \quad (34)$$

This relation together with current conservation is proven in Appendix C. The factor p shows clearly that $\Sigma^{\alpha\pm}$ describes the contribution to the current rate. In contrast to lowest order processes, i.e., the golden rule rate, where p can only take the values ± 1 , p can be arbitrary for higher order processes. Nevertheless, Eq. (33) shows that the current rate can be calculated as a partial selection of diagrams already contained in the total transition rate $\Sigma_{\chi', \chi}$.

We emphasize that the current formula (32) together with the Master equation (26) constitutes a complete theory to describe time-dependent phenomena starting from an arbitrary diagonal initial state. The original problem has now been shifted to the evaluation of the various self-energy diagrams which correspond to transition and current rates. The self-energies are defined by a set of irreducible diagrams and thus their corresponding perturbation expansion in the number of tunneling lines is a well-defined series and contains no divergent time-integrals.

For time-translational invariant systems the current rates $\Sigma_{\chi', \chi}^{\alpha\pm}(t', t)$ depend only on the time difference $t' - t$. To calculate the stationary current we define in analogy to (30)

$$\Sigma_{\chi', \chi}^{\alpha\pm} = i \int_{-\infty}^0 dt' \Sigma_{\chi', \chi}^{\alpha\pm}(t', 0) \quad (35)$$

which again can be calculated directly with our diagrammatic rules in energy space. The stationary current is then given by

$$I_\alpha^{st} = -ie \sum_{\chi, \chi'} P_{\chi'}^{st} \Sigma_{\chi', \chi}^{\alpha+} = ie \sum_{\chi, \chi'} P_{\chi'}^{st} \Sigma_{\chi', \chi}^{\alpha-}. \quad (36)$$

D. Green's functions

After the unitary transformation the Green's functions of the dot electrons read

$$G_\sigma^>(t, t') = -i \langle (c_\sigma e^{i\varphi})(t) (c_\sigma^\dagger e^{-i\varphi})(t') \rangle \quad (37)$$

$$G_\sigma^<(t, t') = i \langle (c_\sigma^\dagger e^{-i\varphi})(t') (c_\sigma e^{i\varphi})(t) \rangle. \quad (38)$$

Here $G_\sigma^>$ and $G_\sigma^<$ are independent quantities since we do not assume equilibrium. For time-translational invariant systems, the Green's functions depend only on the time difference $G(t, t') = G(t - t')$. The Fourier transform $G(E) = \int dt e^{iEt} G(t)$ can be written in the form

$$G_\sigma^>(E) = 2i \operatorname{Im}(-i) \int_{-\infty}^0 dt e^{-iEt} \langle T_K(c_\sigma e^{i\varphi})(0) (c_\sigma^\dagger e^{-i\varphi})(t^+) \rangle \quad (39)$$

$$G_\sigma^<(E) = -2i \operatorname{Im}(-i) \int_{-\infty}^0 dt e^{-iEt} \langle T_K(c_\sigma e^{i\varphi})(0) (c_\sigma^\dagger e^{-i\varphi})(t^-) \rangle, \quad (40)$$

where $t^\pm$ means that the time t lies on the upper (lower) branch of the Keldysh contour. Note that the time ordering is defined here by a pure ordering along the Keldysh contour without any sign change if we interchange fermion operators. The integrals can be calculated like Eq. (21) whereby instead of assigning the energy $-E$ to the virtual line connecting the external vertices one can change the direction of the line and assign the energy E .

In order to relate the current to the Green's functions of the dot we consider the first diagram on the r.h.s. of Fig. 4 (the second one is just the conjugate complex). The external vertex can be either contracted by a tunneling line to the upper or lower propagator and we recover immediately the structure of the Green's functions $G^>$ and $G^<$, respectively (see Fig. 5). We recover for the stationary current the relation^{52,13,14}

$$I_\alpha^{st} = -ie \sum_\sigma \int dE \{ \gamma_\alpha^+(E) G_\sigma^>(E) + \gamma_\alpha^-(E) G_\sigma^<(E) \}. \quad (41)$$

In the case that the couplings to the leads have the same energy dependence, $\Gamma_\alpha(E)/\Gamma_{\alpha'}(E) = \lambda_{\alpha,\alpha'}$, this can be written in the form (which was already derived in Ref. 14),

$$I_\alpha^{st} = e \sum_{\alpha'} \sum_\sigma \int dE \frac{\Gamma_\alpha(E) \Gamma_{\alpha'}(E)}{\sum_{\alpha''} \Gamma_{\alpha''}(E)} \rho_\sigma(E) [f_{\alpha'}^+(E) - f_\alpha^+(E)]. \quad (42)$$

Here, we used the relation between the Green's functions $G_\sigma^<, G_\sigma^>$ and spectral density $\rho_\sigma \equiv \frac{G_\sigma^< - G_\sigma^>}{2\pi i}$.

IV. RESULTS

What we have done so far is to derive a diagrammatic language which allows a systematic description of transport processes. We have, furthermore, shown how the physical quantities of interest, the stationary probability distribution and the current, can be obtained if we know the value of special diagrams. In this section, now, we will explicitly calculate the value of the corresponding diagrams.

We consider here the case of strong Coulomb repulsion U , i.e., we restrict ourselves to the states with $N = 0, 1$. Diagrams in which a higher occupancy occurs do not contribute since they have resolvents of the order $1/U$.

In the following, the index σ labels the singly occupied state with spin $\sigma = 1, \dots, M$. The label χ additionally allows an empty dot, $\chi = 0, 1, \dots, M$.

In general, we can not sum up *all* possible diagrams. Therefore, we have to find a systematic criterion which diagrams should be retained and summed.

The simplest approximation is to neglect all diagrams where two or more tunneling lines overlap in time (see the leftmost diagram parts in Fig. 2). This means we include those processes which are also described by the master equation with rates obtained in lowest order perturbation theory (sequential tunneling), which is a good description at high temperature, $\Gamma \ll T$.

In situations when sequential tunneling is suppressed by Coulomb blockade, the lowest order contribution to the current arises due to cotunneling. The rates for a process in which an electron enters the dot from the left lead and leaves to right one is described by diagrams with two overlapping lines (see the diagram part in the middle of Fig. 2).

At lower temperature the perturbative approach is not sufficient. Higher-order processes become important. In generalization to cotunneling we have to take into account irreducible diagrams with an arbitrary number of correlated tunneling processes, i.e., we include resonant tunneling.

Similar to the case of metallic islands^{34,35} we proceed in a conserving approximation, taking into account non-diagonal matrix elements of the total density matrix up to the difference of one electron-hole pair excitation in the leads. The graphical representation of this constriction is that only diagrams in which any vertical line will cut at most two tunneling lines are taken into account.

We give two arguments why this class of diagrams is the most important one. Firstly, since we treat the leads as large equilibrium reservoirs there should be a tendency of the system to stay close to diagonal states. Secondly, our approximation contains the exact solution for the noninteracting limit $U = 0$: if there is no electron-electron interaction in the dot, electrons with different spin do not influence each other, so that this limit is described within our model by choosing $M = 1$. In this case, the selected diagrams are the only contributing ones. The sum of all other, more complicated, diagrams is zero.

Furthermore, we include only boson lines between vertices which are already connected by tunneling lines, i.e.,

$$C_B(t_1, t_2, \dots, t_m, t'_1, t'_2, \dots, t'_m) \approx \prod_{i=1}^m P^K(t_i, t'_i). \quad (43)$$

where the pairs t_i, t'_i are already coupled by tunneling lines running from t'_i to t_i . This amounts to a dressing of the tunneling lines $\bar{\gamma} \rightarrow \gamma$. This approximation, while neglecting many diagrams, describes well the spectral density of the dot at resonance points. The reason is that position and value of the peaks of the spectral density are determined by a self-energy σ (see Eq. (49)) which is calculated here in lowest order perturbation theory in Γ including the bosons. Higher orders are small for high tunnel barriers.

First, we relate the rate $\Sigma_{\chi',\chi}$ to an irreducible diagram labeled by $\phi_{\chi'_2,\chi_2}^{\chi'_1,\chi_1}(\alpha, \sigma, E)$ (see Fig. 6). It has an open tunneling line associated with tunneling of an electron with spin σ in the junction α carrying the energy E . The line is directed from the right to the left and its value together with the corresponding resolvent is included in ϕ . The self-energy is then constructed by attaching the open tunneling line of these diagrams to the upper and lower propagator (see Fig. 7) with the result

$$\begin{aligned}\Sigma_{\chi',\chi} &= 2i \text{Im} \int dE \sum_{\sigma,\alpha} \sum_{\chi_1} \left\{ \langle \chi | c_\sigma | \chi_1 \rangle \phi_{\chi'_2,\chi_2}^{\chi'_1,\chi_1}(\alpha, \sigma, E) - \langle \chi_1 | c_\sigma | \chi \rangle \phi_{\chi'_2,\chi_2}^{\chi'_1,\chi}(\alpha, \sigma, E) \right\} \\ &= \sum_{\alpha} \left\{ \Sigma_{\chi',\chi}^{\alpha+} + \Sigma_{\chi',\chi}^{\alpha-} \right\}.\end{aligned}\quad (44)$$

where the current rates $\Sigma_{\chi',\chi}^{\alpha\pm}$ correspond to the first and second term, respectively. Again we have made use of the fact that a diagram becomes the conjugate complex if we change the vertical position of all vertices and the direction of all tunneling and boson lines. As pointed out in Appendix C, any approximation for ϕ will lead to a current conserving theory.

We construct the diagram ϕ by iteration (see Figs. 8 and 9). To do so, we need the diagram $\pi(E)$ which is the propagator $\pi(E)$ while a tunneling line with energy E is running in parallel from the right to the left. This diagram can also be expressed as an iteration in the style of a Dyson equation (see Fig. 10)

$$\pi_{\chi'_2,\chi_2}^{\chi'_1,\chi_1}(E) = \pi_{\chi'_2}^{(0)\chi'_1}(E) \delta_{\chi'_1,\chi_1} \delta_{\chi'_2,\chi_2} + \sum_{\chi'_1,\chi'_2} \pi_{\chi'_2,\chi'_2}^{\chi'_1,\chi'_1}(E) \sigma_{\chi'_2,\chi_2}^{\chi'_1,\chi_1}(E) \pi_{\chi_2}^{(0)\chi_1}(E). \quad (45)$$

In analogy to Σ , the self-energy $\sigma(E)$ denotes the sum of all irreducible diagrams with a tunneling line going backward in time. Here, the free propagator in energy space is given by

$$\pi_{\chi_2}^{(0)\chi_1}(E) = \frac{1}{E - (\epsilon_{\chi_1} - \epsilon_{\chi_2}) + i0^+} \quad (46)$$

Hence, we can solve Eq. (45) and find in matrix notation the general relation

$$\pi(E) = [[\pi^{(0)}(E)]^{-1} - \sigma(E)]^{-1}. \quad (47)$$

Because of the restriction to two charge states, only the matrix elements $\pi^\sigma(E) \equiv \pi_{0,0}^{\sigma,\sigma}(E)$ of $\pi(E)$ and $\sigma^\sigma(E) \equiv \sigma_{0,0}^{\sigma,\sigma}(E)$ of $\sigma(E)$ are involved, and we deduce from Eq. (47)

$$\pi^\sigma(E) = \frac{1}{E - \epsilon_\sigma - \sigma^\sigma(E)}. \quad (48)$$

Since at most two tunneling lines are allowed at once, the irreducible self-energy $\sigma^\sigma(E)$ consists of only one tunneling line. We calculate all contributions, which are depicted in Fig. 11, and get

$$\sigma^\sigma(E) = \int dE' \frac{\gamma^-(E')}{E - E' + i0^+} + \sum_{\sigma'} \int dE' \frac{\gamma^+(E')}{E - E' + \epsilon_{\sigma'} - \epsilon_\sigma + i0^+}. \quad (49)$$

In the spin degenerate case, this is exactly the relation (10) which we found from intuitive arguments.

According to our rules, Figs. 8 and 9 lead to the self-consistent equation for the diagram $\phi(\alpha, \sigma, E)$

$$\begin{aligned}\phi_{0,0}^{0,\sigma}(\alpha, \sigma, E) &= \pi^\sigma(E) \left[\gamma_\alpha^+(E) - \gamma_\alpha^-(E) \sum_{\alpha'} \int dE' \frac{1}{E - E' + i0^+} \phi_{0,0}^{*,0,\sigma}(\alpha', \sigma, E') \right. \\ &\quad \left. - \gamma_\alpha^+(E) \sum_{\sigma'} \sum_{\alpha'} \int dE' \frac{1}{E - E' + \epsilon_{\sigma'} - \epsilon_\sigma + i0^+} \phi_{0,0}^{*,0,\sigma'}(\alpha', \sigma', E') \right]\end{aligned}\quad (50)$$

and

$$\begin{aligned} \phi_{\sigma',0}^{\sigma',\sigma}(\alpha, \sigma, E) = \pi^\sigma(E) & \left[-\gamma_\alpha^-(E) \delta_{\sigma\sigma'} - \gamma_\alpha^-(E) \sum_{\alpha'} \int dE' \frac{1}{E - E' + i0^+} \phi_{\sigma',0}^{*\sigma',\sigma}(\alpha', \sigma, E') \right. \\ & \left. - \gamma_\alpha^+(E) \sum_{\sigma''} \sum_{\alpha'} \int dE' \frac{1}{E - E' + \epsilon_{\sigma'} - \epsilon_\sigma + i0^+} \phi_{\sigma',0}^{*\sigma',\sigma''}(\alpha', \sigma'', E') \right] \end{aligned} \quad (51)$$

The stationary probabilities and the current are derived from Eqs. (29) and (36). To calculate the rates we specify Eq. (44) and obtain

$$\Sigma_{\chi',0}^{\alpha+} = 2i \operatorname{Im} \sum_{\sigma} \int dE \phi_{\chi',0}^{\chi',\sigma}(\alpha, \sigma, E), \quad (52)$$

$$\Sigma_{\chi',\sigma}^{\alpha-} = -2i \operatorname{Im} \int dE \phi_{\chi',0}^{\chi',\sigma}(\alpha, \sigma, E), \quad (53)$$

whereas all other rates are zero.

The correlation functions can be calculated from the diagrams shown in Figs. 12 and 13. We have to consider only the latest (i.e. rightmost) correlated part of the diagram. The processes before end up with probability P_χ^{st} in a diagonal state χ . We have used the same criterion as for the calculation of the density matrix with one exception. If a vertical line lies between the external vertices we allow a cut through at most one tunneling line. Here we have used the fact that such a vertical line will in addition always cut the virtual line connecting the external vertices. The sum of all these diagrams gives (where we can combine always two diagrams to the imaginary part of one of them)

$$G_\sigma^>(E) = \int dE' \bar{G}_\sigma^>(E') P^+(E' - E) \quad (54)$$

$$G_\sigma^<(E) = \int dE' \bar{G}_\sigma^<(E') P^-(E' - E) \quad (55)$$

with

$$\bar{G}_\sigma^>(E) = 2i \operatorname{Im} \left\{ \pi^\sigma(E) \left[P_0^{st} - \sum_{\alpha} \sum_{\sigma'} \int dE' \frac{P_0^{st} \phi_{0,0}^{*0,\sigma'}(\alpha, \sigma', E') + \sum_{\sigma''} P_{\sigma''}^{st} \phi_{\sigma'',0}^{*\sigma'',\sigma'}(\alpha, \sigma', E')}{E - E' + \epsilon_{\sigma'} - \epsilon_\sigma + i0^+} \right] \right\} \quad (56)$$

$$\bar{G}_\sigma^<(E) = -2i \operatorname{Im} \left\{ \pi^\sigma(E) \left[P_\sigma^{st} + \sum_{\alpha} \int dE' \frac{P_0^{st} \phi_{0,0}^{*0,\sigma}(\alpha, \sigma, E') + \sum_{\sigma'} P_{\sigma'}^{st} \phi_{\sigma',0}^{*\sigma',\sigma}(\alpha, \sigma, E')}{E - E' + i0^+} \right] \right\}. \quad (57)$$

In the following, we discuss for transparency the effect of the coupling to bosons and the presence of a magnetic field separately.

A. Boson-assisted tunneling

For zero magnetic field, i.e. $\epsilon_\sigma = \epsilon$ for all σ , we can perform the resummation of the corresponding diagrams for the rates and the Green's functions analytically (details are given in Appendix D) and find

$$I_\alpha^{st} = 2\pi e M \sum_{\alpha'} \int dE [\gamma_\alpha^-(E) \gamma_{\alpha'}^+(E) - \gamma_{\alpha'}^-(E) \gamma_\alpha^+(E)] |\pi(E)|^2 \quad (58)$$

with $\pi(E) = \pi^\sigma(E)$. We can write this equation in a more intuitive way by inserting the definition (7) for $\gamma_\alpha^\pm$

$$I_\alpha^{st} = \frac{e}{h} \sum_{\alpha'} \int dE \int dE' \{ T_{\alpha',\alpha}(E', E) f_{\alpha'}(E') (1 - f_\alpha(E)) - T_{\alpha,\alpha'}(E, E') f_\alpha(E) (1 - f_{\alpha'}(E')) \}, \quad (59)$$

where

$$T_{\alpha,\alpha'}(E, E') = M \Gamma_\alpha(E) \Gamma_{\alpha'}(E') \int dE_1 P^+(E_1 - E) P^-(E_1 - E') |\pi(E_1)|^2 \quad (60)$$

can be interpreted as a transmission probability for an electron to start from reservoir α with energy E and end in reservoir α' with energy E' . From the detailed balance condition (9) we get

$$T_{\alpha',\alpha}(E', E) = e^{\beta(E' - E)} T_{\alpha,\alpha'}(E, E'). \quad (61)$$

This guarantees that the current is zero if all chemical potentials of the reservoirs are identical.

However, the interpretation of $T_{\alpha,\alpha'}$ as a one-particle transmission probability in analogy to a generalization of the Landauer-Büttiker formula to inelastic interactions⁵¹ is not correct. We see that the transmission probability still depends on the Fermi distribution functions via the self-energy $\sigma(E)$ in the denominator of the propagator $\pi(E)$. This reflects the many-particle aspect of the electron-electron and electron-boson interaction in our model.

Comparing our result for $T_{\alpha,\alpha'}$ with other approaches in the case $M = 1$ ^{39-41,45}, we see that the energy dependence of $\sigma(E)$ has been neglected in all previous treatments. We find that even in the $M = 1$ case, the energy dependence of $\sigma(E)$ cannot be neglected if the temperature T and the typical frequency ω_B of the bosons are smaller than Γ .

Without bosons, the current formula is exact up to order $O(\Gamma^2)$, i.e., sequential and electron cotunneling are fully taken into account. With bosons, cotunneling is not described correctly since we have treated the bosons only by a dressing of the tunneling lines. This means that our approximation is not valid in regions where the current is very small. However, at resonance we believe our treatment to be correct since there we expect that sequential tunneling will be just modified by a renormalization and broadening of the local state of the dot which is described by the self-energy $\sigma(E)$ which is calculated in lowest order in Γ here. Higher orders will be small for high tunneling barriers.

Finally, we calculate the Green's functions and find

$$G^>(E) = -2\pi i \int dE' \gamma^-(E') P^+(E' - E) |\pi(E')|^2 \quad (62)$$

$$G^<(E) = 2\pi i \int dE' \gamma^+(E') P^-(E' - E) |\pi(E')|^2. \quad (63)$$

In equilibrium, i.e. $\mu_\alpha = 0$ for all α , we obtain the correct sum rule $G^>(E) = -\exp(\beta E) G^<(E)$. Furthermore, for the $M = 1$ case, particle-hole symmetry is satisfied. The spectral density has the form

$$\rho(E) = \int dE' [\gamma^+(E') P^-(E' - E) + \gamma^-(E') P^+(E' - E)] |\pi(E')|^2. \quad (64)$$

The effect of the resonant-tunneling processes is described by the resolvent $\pi(E)$ containing the self-energy $\sigma(E)$, Eq. (49). The real and imaginary part of the self-energy express energy renormalization and broadening and determine, therefore, the position and the width of the maxima in the spectral density.

To proceed we consider from now on a one-mode environment (Einstein model) with boson frequency $\omega_q = \omega_B$. Experimentally realizations of this model are optical phonons³⁹⁻⁴¹ or by fluctuations of an external LC -circuit with frequency⁴²⁻⁴⁵ $\omega_B = (LC)^{-1/2}$. The results for a general environment can be anticipated approximately from the one-mode case by a superposition. Furthermore, we choose the special case of two reservoirs $\alpha = L/R$ and constant level broadening $\Gamma/2 = \Gamma_L = \Gamma_R$.

Defining $g = \sum_q g_q^2 / \omega_B^2$ we obtain $P^\pm(E) = \sum_n p_n \delta(E \pm n\omega_B)$, where $p_n = e^{-g(1+2N_0(\omega_B))} e^{n\omega_B/2T_B} I_n(2gN_0(\omega_B)e^{\omega_B/2T_B})$ is the probability for the emission of n bosons with frequency ω_B . Here, $N_0(\omega_B)$ is the Bose function and I_n the modified Bessel function. Using Eq. (49) we obtain¹⁵

$$\text{Re } \sigma(E) = \sum_{n,\alpha} (M p_n - p_{-n}) \frac{\Gamma_\alpha}{2\pi} \left[\ln \left(\frac{E_C}{2\pi T} \right) - \text{Re } \Psi \left(\frac{1}{2} + i \frac{E + n\omega_B - \mu_\alpha}{2\pi T} \right) \right] \quad (65)$$

$$\text{Im } \sigma(E) = -\pi \sum_n p_n [M \bar{\gamma}^+(E + n\omega_B) + \bar{\gamma}^-(E - n\omega_B)]. \quad (66)$$

Here Ψ denotes the digamma function, and we have chosen in the energy integrals a Lorentzian cut-off at E_C .

The real part of $\sigma(E)$ renormalizes the level position to higher energies. Furthermore, it depends logarithmically on energy, temperature, voltage and frequency. These logarithmic terms are typical for the occurrence of Kondo peaks. Hence, we anticipate logarithmic singularities either for $M \geq 2$ or for $p_n \neq p_{-n}$. This includes not only the degenerate case but also the case of a single dot level without spin ($M = 1$) since the probabilities for absorption and emission of bosons are different. It is important to remark here, that for systems coupled to classical time-dependent fields²² the situation is different since then both probabilities are equal. At low enough temperatures we obtain logarithmic peaks

in $\sigma(E)$ at $E = \mu_\alpha + n\omega_B$ ($n \neq 0$ for $M = 1$). They lead to maxima of the resolvent $\pi(E)$ at $E = \mu_\alpha + n\omega_B$ ($n > 0$ for $M = 1$, $n \geq 0$ for $M > 1$) for $\epsilon < 0$ and at $E = \mu_\alpha + n\omega_B$ ($n < 0$) for $\epsilon > 0$. The spectral density (64) shows resonances at the same points but, due to the additional $P^\pm$ functions in the integrand, they are shifted by multiples of ω_B . This boson-assisted tunneling is completely independent from the influence of the bosons on the self-energy $\sigma(E)$.

The spectral density at different voltages for a low lying level $\epsilon < 0$ is depicted in Fig. 14. Without an applied bias voltage, we obtain (for $M = 2$) the usual Kondo peak near the Fermi level (which we choose as zero energy). The emission of bosons leads to additional resonances at multiples of ω_B . For $M = 1$ and $\epsilon < 0$, resonances occur for negative energies and in the case $\epsilon > 0$ we find resonances at positive energies. In these cases, the effects are less pronounced and are only visible for very low temperatures. At finite bias voltages all peaks split and decrease in magnitude.

The resonances in the spectral density can be probed by the nonlinear differential conductance as function of the bias voltage V , as shown in Fig. 15 for the case $\epsilon < 0$. The splitting of the Kondo peak leads to an overall decrease of the spectral density in the energy range $|E| < eV$ (see inset of Fig. 15). For this reason, the conductance shows the well-known^{14,22,24} maximum at zero bias. The emission of bosons produces a set of symmetric satellite maxima. They can be traced back to the fact that pairs of Kondo peaks can merge if the bias voltage is a multiple of the boson frequency (see Fig. 14). This gives rise to pronounced Kondo peaks at $E = \pm eV/2$ and thus to an increase of the spectral density with bias voltage near these points.

Fig. 16 shows the differential conductance for $\epsilon \geq 0$ with and without bosons. A striking result is that the whole structure is inverted compared to the case $\epsilon < 0$, and we find a zero-bias anomaly although the Kondo peak at zero energy is absent. The coupling to bosons yields satellite steps at $|eV| = n\omega_B$. The contributions of sequential and cotunneling lead, compared to resonant tunneling, only to a weak bias voltage dependence of the differential conductance. This shows clearly that the influence of the logarithmic terms in $\sigma(E)$ are still important. The logarithmic peaks in $\text{Re } \sigma(E)$ decrease with increasing bias voltage and approach the value of $E - \epsilon$ if ϵ is large enough. Thus the value of $E - \epsilon - \text{Re } \sigma(E)$ decreases which in turn leads to an overall increase of the resolvent $\pi(E)$ and the spectral density $\rho(E)$ near zero energy (see the inset of Fig. 16).

Zero-bias minima are known from Kondo scattering from magnetic impurities.⁵³ They have been observed in recent experiments⁵⁴ and have been interpreted as 2-channel Kondo scattering from atomic tunneling systems^{55,56} or by tunneling into a disordered metal.⁵⁷ Here we have shown that zero-bias minima can also arise due to resonant tunneling via local impurities if the level position is high enough such that we are in the mixed valence regime.

Finally, we have investigated the differential conductance at fixed bias voltage as function of the position of the dot level, which experimentally can be varied by a gate voltage coupled capacitively to the dot (see Fig. 17). The result shows a (classical) pair of peaks at $|\epsilon| = eV/2$ together with satellites (due to emission and absorption of bosons) and peaks for $|\epsilon| > eV/2$ (only due to absorption). The energy dependence of $\text{Im } \sigma(E)$ gives rise to an asymmetry of the peak heights. The peak at $\epsilon = eV/2$ is higher than the one at $\epsilon = -eV/2$ since $|\text{Im } \sigma(E)| = \pi|M\gamma^+(E) + \gamma^-(E)|$ is smaller for higher energies (except for $M = 1$ when particle-hole symmetry holds). This significant effect is due to the broadening of the spectral density by quantum fluctuations.

B. Magnetic field dependence

In this section we discuss the effect of an applied magnetic field and do not take into account the coupling to bosons. Again we consider the case of two reservoirs and constant level broadenings. Since the energy levels ϵ_σ are now spin dependent, we can no longer solve the self-consistent equations analytically but have to solve them numerically.

We find Kondo resonances in the spectral density $\rho_\sigma(E)$ at energies $E = \mu_\alpha + \epsilon_{\sigma'} - \epsilon_\sigma$ with $\sigma' \neq \sigma$. This is due to the fact, that the correlation functions $G_\sigma^<(E)$ and $G_\sigma^>(E)$ are mainly determined by the resolvent $\pi^\sigma(E)$ (see Eqs. (56) and (57)) which contains via the self-energy $\sigma^\sigma(E)$ logarithmic singularities at the corresponding energies,

$$\text{Re } \sigma^\sigma(E) = \sum_\alpha \frac{\Gamma_\alpha}{2\pi} \sum_{\sigma' \neq \sigma} \left[\ln \left(\frac{E_C}{2\pi T} \right) - \text{Re } \Psi \left(\frac{1}{2} + i \frac{E + \epsilon_{\sigma'} - \epsilon_\sigma - \mu_\alpha}{2\pi T} \right) \right] \quad (67)$$

$$\text{Im } \sigma^\sigma(E) = -\pi \left[\bar{\gamma}^-(E) + \sum_{\sigma'} \bar{\gamma}^+(E + \epsilon_{\sigma'} - \epsilon_\sigma) \right]. \quad (68)$$

From Eq. (42) we see that only energies within the window defined by the difference of the Fermi functions contribute to the current. For this reason, there is no Kondo-assisted tunneling at low transport voltage but sets on if transport voltage and level splitting are equal. Therefore, for low lying levels the conductance peak at zero bias found in the previous section now splits up into two peaks separated by the twice the level splitting¹⁴ (see Fig. 18).

Ralph and Buhrman recently measured Kondo-assisted tunneling via a single charge trap of a point contact tunnel barrier.²⁴ We follow the model proposed by the authors interpreting the experiment as a realization of the Anderson model with strong Coulomb repulsion such that double occupancy does not occur. However we think that the interaction energy U and not the conduction band width is the relevant cut-off in this situation.

A comparison of the experiment and our theory is given in Fig. 18, Fig. 19 and Fig. 20. We find a good agreement for the peaks induced by Kondo-assisted tunneling processes if we set the cut-off $U = 30\text{meV}$. The authors suspect the single-charge trap to be a dangling bond, for which they expect $U = 100\text{meV}$. Our result agrees in the order of magnitude, it gives a hint however, that the state may have a larger extension than an ordinary dangling bond or that there is screening due to the copper electrodes or both. The peaks for larger magnetic fields show, however, a stronger broadening than predicted from our calculation. Nevertheless, our theory reproduces the experimental curves much better than the fits given in Ref. 24 using perturbation theory since we have taken into account nonperturbative effects which are obviously important here.

The model proposed by the authors of Ref. 24 explains the broad peaks at large voltages by the matching of the energies of the empty and the singly occupied dot. Our calculations for this case, however, lead to a broader and lower peak for positive voltages in comparison with experiment (see Fig. 19). We think, therefore, that due to the capacitance asymmetry the system becomes doubly occupied before the empty state is energetically favorable. The capacitance asymmetry a_c makes then the corresponding resonance peak sharper. An energy dependent transparency of the barriers could then explain the different heights. A generalization of our theory to situations, where multiple occupancy of the dot is important, is currently under way and will be presented elsewhere.

Finally, we consider the case when the energy level is above the Fermi energies of the leads. The zero-bias minimum found in the previous section splits for finite magnetic field into two minima separated by twice the level splitting (see Fig. 21).

V. CONCLUSIONS

In conclusion, we have studied low-temperature transport in the nonequilibrium Anderson model with bosonic interactions. The latter yield new Kondo resonances in the spectral density which can be probed by the measurement of the nonlinear differential conductance. Both the gate and bias voltage dependence are important. Quantum fluctuations due to resonant tunneling yield zero-bias anomalies as function of the bias voltage, *which can be changed from maxima to minima by varying the gate voltage*. We, furthermore, discussed the splitting of the zero-bias anomaly by an external magnetic field and found good agreement with recent experiments.

We have presented a real-time approach which is based on a nonperturbative calculation of transition rates between different states of a local strongly correlated system coupled to fermionic or bosonic baths. We present systematic rules of how to set up well defined perturbation expansions for the rates in terms of the tunneling matrix elements between dot and leads. The formally exact rates are used to calculate occupation probabilities and the current from Master equations and current formulas which are intuitively obvious. The method has a wide applicability, ranging from the study of arbitrary dot level structures up to the investigation of macroscopic quantum coherence phenomena. The latter can arise from the time evolution of non-stationary initial states or by the application of explicitly time-dependent fields.

The usage of real-time methods to understand low-temperature behavior of strongly correlated fermions either in equilibrium or non-equilibrium situations is a rather new field and has not yet been applied extensively. Compared with the conventional methods in imaginary time⁵⁹ they offer the possibility to set up new approximation schemes. In this paper we have performed a nonperturbative resummation of higher order coherent tunneling processes to calculate transition and current rates analytically for temperatures smaller than the intrinsic broadening Γ . Although the criterium for considering certain diagrams is yet not motivated by the usage of a “small” parameter, the diagrams are selected in a systematic way. We have chosen all diagrams which keep the total density matrix as close as possible to the diagonal state up to one electron-hole pair excitation in the reservoirs. This reminds of techniques applied within variational wave function ansatzes⁶⁰ but here formulated on the basis of density matrices for nonequilibrium systems at finite temperatures. Furthermore, there are many possibilities to improve our approximation by considering more diagrams by analytical or numerical methods. Simple limiting cases as e.g. the noninteracting case are already exactly incorporated within our approximation. Since the strongly interacting case gives also at least qualitatively good results, our method may be a good candidate to cover the whole range from weak to strong interaction within the same approximation scheme.

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APPENDIX A: THE RULES IN TIME SPACE

Each term of the expansion Eq. (17) with operators A_i of the form Eq. (18) can be calculated according to the following rules:

1. Draw all topological different diagrams with directed tunneling lines connecting pairs of internal or external vertices containing lead electron operators. Assign a reservoir index α and a spin index σ to each of these lines. Connect all vertices containing boson operators in all possible ways by boson lines. Assign states χ and the corresponding energy ϵ_χ to each element of the Keldysh contour connecting two vertices.
2. The propagation from t' to t with $t' < t$ on the Keldysh contour implies a factor $\exp[-i\epsilon_\chi(t - t')]$.
3. The state χ which is assigned to the left most part of the diagram implies a factor P_χ^0 from the initial density matrix. Each vertex containing a dot operator B gives rise to a matrix element $\langle \chi' | B | \chi \rangle$ where χ (χ') is the dot state entering (leaving) the vertex with respect to the Keldysh contour.
4. Each directed tunneling line with index α running from t' to t implies $(-1)^v \bar{\gamma}_\alpha^K(t, t')$ with v being the number of electron operators (due to external vertices) on the part of the Keldysh contour from t' to t . The line corresponds to a tunneling process in reservoir α . Each boson line connecting vertices at times t and t' implies $P^K(t, t')$ if the phase factors at these vertices have different sign. Otherwise, the boson line has the value $P^K(t, t')^{-1}$.
5. Each diagram carries a prefactor $(-i)^m (-1)^c$, where m is the total number of internal vertices and c the number of crossings of tunneling lines. There may be a further minus sign due to the order of dot electron operators which emerges from the matrix elements $\langle \chi' | B | \chi \rangle$ discussed in rule 3.
6. Integrate over the internal times along the Keldysh contour without changing their ordering and sum over the reservoir and spin indices.

We emphasize that these diagrammatic rules hold for arbitrary dot Hamiltonians $\bar{H}_D = \sum_\chi \epsilon_\chi |\chi\rangle \langle \chi|$, i.e., the states χ can be many-body eigenfunctions of $\bar{H}_D$ containing complicated correlations due to Coulomb interaction, magnetic fields, geometric setups, etc. . Such eigenfunctions have been calculated for special situations^{49,50} and can be used as an input for our diagrammatic language. In this paper, however, we will concentrate ourselves on the dot Hamiltonian (5) where the states χ are trivially known. For this special case, the matrix elements $\langle \chi' | B | \chi \rangle$ from rule 3 can only give rise to minus signs whereas they can have a more pronounced influence in more general situations^{49,50}.

Furthermore, we note that the same diagrammatic rules even hold for arbitrary time-dependent dot Hamiltonians $\bar{H}_D(t)$ which are not diagonal in the states χ . In this case one has to assign two states χ' and χ to the beginning and the end of each element of the Keldysh contour, respectively. The factor $\exp[-i\epsilon_\chi(t - t')]$ from rule 2 is then replaced by the matrix element $\langle \chi | U_D(t, t') | \chi' \rangle$ where U_D denotes the time evolution operator of $\bar{H}_D$ and t (t') are the times at the end (beginning) of the element of the Keldysh contour.

APPENDIX B: THE RULES IN ENERGY SPACE

We obtain the diagrammatic rules in energy space by expanding the expectation value in Eq. (21) and then performing the time integrals. We order the times of all internal (m) and external vertices (n) from left to right and label them by τ_j with $j = 1, 2, \dots, m + n$ (with $\tau_{m+n} = 0$), irrespective on which branch they are. The Keldysh contour integrals are now written as ordinary integrals. This includes a minus sign for each internal vertex on the backward propagator. If the initial density matrix is diagonal we then encounter expressions of the type

$$\begin{aligned} & \int_{-\infty}^0 d\tau_1 \int_{\tau_1}^0 d\tau_2 \dots \int_{\tau_{m+n-2}}^0 d\tau_{m+n-1} e^{0^+ \tau_1} e^{-i\Delta E_1(\tau_1 - \tau_2)} e^{-i\Delta E_2(\tau_2 - \tau_3)} \dots e^{-i\Delta E_{m+n-1}\tau_{m+n-1}} \\ & = i^{m+n-1} \frac{1}{\Delta E_1 + i0^+} \cdot \frac{1}{\Delta E_2 + i0^+} \dots \frac{1}{\Delta E_{m+n-1} + i0^+} . \end{aligned} \quad (\text{B1})$$

Here ΔE_j is the difference of all energies going to the left minus all energies going to the right in each segment limited by τ_j and τ_{j+1} . This includes the energies of the propagators and – if present – the energies of the tunneling, boson and virtual lines. The convergence factor $e^{0^+ \tau_1}$ is related to an adiabatic switching on of the tunneling term $\bar{H}_T$. The factor i^{m+n-1} cancels with the factor $(-i)^m$ from rule 4 above together with the prefactor $(-i)^{n-1}$ from the definition Eq. (B1). Therefore, the corresponding rules in energy representation read:

- 1'. Draw all topologically different diagrams with fixed ordering of the vertices along the real axis, i.e., irrespective on which branch they are. The vertices are connected by tunneling and boson lines as in time space. In addition to the energy ϵ_χ assigned to the propagators we assign an energy E to each tunneling line. For each boson line choose a direction (arbitrarily) and assign also an energy E . The external vertices are connected by virtual lines with energies E_i ($i = 2, \dots, n$) as described above.
- 2'. For each segment derived from $\tau_j \leq \tau \leq \tau_{j+1}$ with $j = 1, 2, \dots, m+n-1$ assign a resolvent $\frac{1}{\Delta E_j + i0^+}$ where ΔE_j is the difference of the leftgoing minus the rightgoing energies (including the energies of the tunneling, boson and virtual lines).
- 3'. See rule 3 in time space.
- 4'. For each coupling of vertices write $(-1)^v \bar{\gamma}_\alpha^+(E)$, if the tunneling line of reservoir α is going backward and $(-1)^v \bar{\gamma}_\alpha^-(E)$, if it is going forward with respect to the closed time path (definition of v see rule 4 in time space). For each boson line write $P^+(E)$, if it is going backward and $P^-(E)$, if it is going forward with respect to the closed time path.
- 5'. The prefactor is given by $(-1)^b (-1)^c$, where b is the total number of internal vertices on the backward propagator and c the number of crossings of tunneling lines. There may be a further minus sign due to the order of dot electron operators which emerges from the matrix elements $\langle \chi' | B | \chi \rangle$ discussed in rule 3.
- 6'. Integrate over the energies of tunneling and boson lines and sum over the reservoir and spin indices.

APPENDIX C: CURRENT CONSERVATION

In this appendix we prove Eq. (34) and current conservation. Let us consider any diagram $\Sigma_{\chi', \chi}^{\alpha p}(t', t)$ in the expression

$$\sum_{\chi} \sum_p p \Sigma_{\chi', \chi}^{\alpha p}(t', t). \quad (C1)$$

By changing the vertical position of the rightmost vertex we get a new diagram which has up to a minus sign the same value as the old diagram from which the new one was constructed. If the rightmost tunneling of the old diagram line has a reservoir index different from α , then the new diagram is of the form $\Sigma_{\chi', \chi''}^{\alpha p}$, so that the sum of all these contributions in Eq. (C1) is zero. The other diagrams are divided into two classes: in the one (the other) class, the rightmost tunneling line of each diagram enters (leaves) the forward propagator or leaves (enters) the backward propagator. The change of the vertical position of the rightmost vertex, then, increases (decreases) the value of p by one, so that the new diagram is of the form $\Sigma_{\chi', \chi''}^{\alpha p \pm 1}$. Furthermore, the old and the new diagram belong to different classes. After changing the position of the rightmost vertex of only one class and then shifting the summation index p in Eq. (C1), we obtain exactly all diagrams of $\sum_{\chi} \Sigma_{\chi', \chi}^{\alpha+}$ which proves Eq. (34).

The conservation of probability follows directly from the master equation (26). Summation over χ together with $\sum_{\chi} \Sigma_{\chi', \chi}(t', t) = 0$ yields

$$\sum_{\chi} \frac{d}{dt} P_{\chi}(t) = 0. \quad (C2)$$

To prove current or charge conservation we first recognize that

$$\sum_{\substack{\chi \\ N(\chi)=p}} \Sigma_{\chi', \chi}^{\alpha+} = - \sum_{\substack{\chi \\ N(\chi)=p+1}} \Sigma_{\chi', \chi}^{\alpha-} \quad (C3)$$

where $N(\chi)$ is the particle number on the dot for state χ . This relation follows directly by changing the vertical position of the rightmost vertex.

After multiplication of the master equation (26) with $-e$ and $N(\chi)$ and summation over χ , we use Eqs. (33) and (C3), insert the current formula (32) and find the conservation law for the total charge flowing into the dot

$$\sum_{\alpha} I_{\alpha}(t) = \frac{d}{dt} Q(t) \quad (C4)$$

where $Q = -eN = -e \sum_{\chi} N(\chi) P_{\chi}$ is the charge on the dot.

In the stationary and time-independent case Eq. (C4) reduces to the conservation of the tunneling current

$$\sum_{\alpha} I_{\alpha}^{st} = 0 \quad (C5)$$

whereas for the general case the r.h.s. of Eq. (C4) is minus the sum over all displacement currents flowing in the reservoirs.

An important result of this appendix is that any approximation for the rates is current conserving provided that the condition Eq. (C3) is satisfied. This means that we always have to consider both vertical positions of the rightmost vertex.

APPENDIX D: ANALYTIC SOLUTION FOR ZERO MAGNETIC FIELD

For zero magnetic field, i.e. $\epsilon_{\sigma} = \epsilon$ for all σ , we define the quantities $\pi(E) \equiv \pi^{\sigma}(E)$, $\sigma(E) \equiv \sigma^{\sigma}(E)$, and

$$\phi_{\alpha}^{+}(E) = \phi_{0,0}^{0,\sigma}(\alpha, \sigma, E) \quad \text{and} \quad \phi_{\alpha}^{-}(E) = \sum_{\sigma'} \phi_{\sigma,0}^{\sigma,\sigma'}(\alpha, \sigma', E) \quad (D1)$$

which are independent of σ . We get the integral equations

$$[E - \epsilon - \sigma(E)]\phi_{\alpha}^{\pm}(E) = \pm \gamma_{\alpha}^{\pm}(E) - \gamma_{\alpha}(E) \int dE' \frac{1}{E - E' + i0^{+}} \phi^{*\pm}(E') \quad (D2)$$

where $\gamma_{\alpha}(E) = \gamma_{\alpha}^{-}(E) + M\gamma_{\alpha}^{+}(E)$ and $\phi^{\pm}(E) = \sum_{\alpha} \phi_{\alpha}^{\pm}(E)$. Summing over α and taking the imaginary part we obtain the solution

$$\text{Im } \phi^{\pm}(E) = \mp \pi \frac{\lambda^{\pm}}{\lambda} \gamma(E) |\pi(E)|^2 \quad (D3)$$

where we used the definitions $\gamma^{\pm}(E) = \sum_{\alpha} \gamma_{\alpha}^{\pm}(E)$, $\gamma(E) = \gamma^{-}(E) + M\gamma^{+}(E)$,

$$\lambda^{\pm} = \int dE \gamma^{\pm}(E) |\pi(E)|^2 \quad \text{and} \quad \lambda = \int dE |\pi(E)|^2. \quad (D4)$$

Furthermore, we obtain directly from (D2) a relation between ϕ_{α} and ϕ

$$\gamma(E) \phi_{\alpha}^{\pm}(E) = \gamma_{\alpha}(E) \phi^{\pm}(E) \pm \pi(E) [\gamma(E) \gamma_{\alpha}^{\pm}(E) - \gamma^{\pm}(E) \gamma_{\alpha}(E)] \quad (D5)$$

Using (52), the current rates follow from $\Sigma_{0,0}^{\alpha+} = 2iM \int dE \text{Im } \phi_{\alpha}^{+}(E)$ and $\Sigma_{\sigma,0}^{\alpha+} = 2i \int dE \text{Im } \phi_{\alpha}^{-}(E)$. With Eqs. (D3) and (D5), the result is

$$\Sigma_{0,0}^{\alpha+} = -2\pi i M \left[\frac{\lambda^{+}}{\lambda} \lambda_{\alpha} + \int dE |\pi(E)|^2 [\gamma^{-}(E) \gamma_{\alpha}^{+}(E) - \gamma^{+}(E) \gamma_{\alpha}^{-}(E)] \right] \quad (D6)$$

$$\Sigma_{\sigma,0}^{\alpha+} = 2\pi i \left[\frac{\lambda^{-}}{\lambda} \lambda_{\alpha} - M \int dE |\pi(E)|^2 [\gamma^{-}(E) \gamma_{\alpha}^{+}(E) - \gamma^{+}(E) \gamma_{\alpha}^{-}(E)] \right], \quad (D7)$$

where $\lambda_{\alpha} = \int dE \gamma_{\alpha}(E) |\pi(E)|^2$.

Summing the current rates over α and using $\sum_{\alpha} \lambda_{\alpha} = \lambda^{-} + M\lambda^{+} = 1$, we get the total transition rates (note that $\Sigma_{\chi',0}^{\alpha-} = 0$)

$$\Sigma_{0,0} = -2\pi i M \frac{\lambda^{+}}{\lambda} \quad \text{and} \quad \Sigma_{\sigma,0} = 2\pi i \frac{\lambda^{-}}{\lambda} \quad (D8)$$

and the solution of the stationary Master equation (29) reads

$$P_0^{st} = \lambda^{-} \quad \text{and} \quad P_{\sigma}^{st} = \lambda^{+} \quad \text{with} \quad \lambda^{-} + M\lambda^{+} = 1. \quad (D9)$$

The stationary current follows from (36) $I_{\alpha}^{st} = -ie[P_0^{st} \Sigma_{0,0}^{\alpha+} + M P_{\sigma}^{st} \Sigma_{\sigma,0}^{\alpha+}]$ (note that $\Sigma_{\chi',\sigma}^{\alpha+} = 0$), which gives as the final result Eq.(58).

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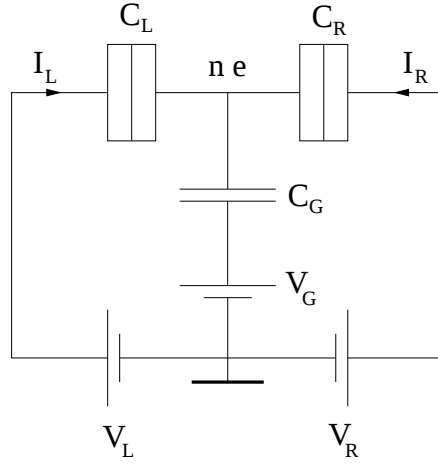


FIG. 1. The SET transistor.

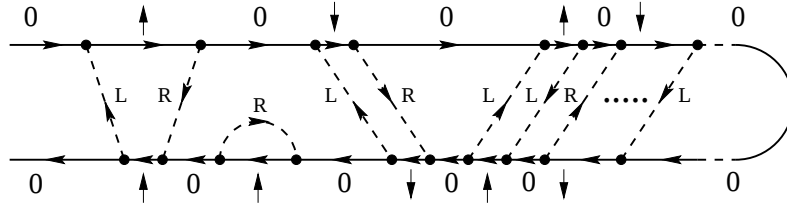


FIG. 2. A diagram showing various tunneling processes: sequential tunneling in the left and right junctions, a term preserving the norm, a cotunneling process, and resonant tunneling.

$$\begin{array}{c} \chi'_1 \\ \rightarrow \end{array} \begin{array}{c} \Pi \\ \leftarrow \end{array} \begin{array}{c} \chi_1 \\ \rightarrow \end{array} = \begin{array}{c} \chi'_1 \\ \rightarrow \end{array} \begin{array}{c} \Pi^{(0)} \\ \leftarrow \end{array} \begin{array}{c} \chi_1 \\ \rightarrow \end{array} + \begin{array}{c} \chi'_1 \\ \rightarrow \end{array} \begin{array}{c} \Pi \\ \leftarrow \end{array} \begin{array}{c} \chi''_1 \\ \rightarrow \end{array} \begin{array}{c} \Sigma \\ \leftarrow \end{array} \begin{array}{c} \chi_1 \\ \rightarrow \end{array} \begin{array}{c} \Pi^{(0)} \\ \leftarrow \end{array} \begin{array}{c} \chi_2 \\ \rightarrow \end{array}$$

FIG. 3. The iteration of processes for the propagator Π .

$$I_\alpha(t) = -ie \sum_\sigma \left\{ \begin{array}{c} \rightarrow \\ \leftarrow \end{array} \begin{array}{c} \alpha, \sigma \\ \rightarrow \end{array} t - \begin{array}{c} \rightarrow \\ \leftarrow \end{array} \begin{array}{c} \alpha, \sigma \\ \rightarrow \end{array} t \right\}$$

FIG. 4. Graphical representation of the current I_α through lead α . Internal vertices are not indicated.

$$I_\alpha^{\text{st}} = 2e \text{Im} \sum_\sigma \left\{ \begin{array}{c} \rightarrow \\ \leftarrow \end{array} \begin{array}{c} \alpha, \sigma \\ \rightarrow \end{array} - \begin{array}{c} \rightarrow \\ \leftarrow \end{array} \begin{array}{c} \alpha, \sigma \\ \rightarrow \end{array} \right\}$$

FIG. 5. Graphical representation of the relation between the current and the correlation functions. Here, the line connecting the external vertices is a real one. Internal vertices are not indicated.

$$\Phi_{\chi'_2, \chi_2}^{\chi'_1, \chi_1}(\alpha, \sigma, E) = \text{Diagram with a box labeled } \Phi \text{ and a dashed line labeled } \alpha, \sigma, E \text{ connecting the right side to the right side.}$$

FIG. 6. Definition of ϕ . It denotes a part of a diagram with an open tunneling line entering from the right.

$$\Sigma_{\chi',\chi} = 2i \operatorname{Im} \left\{ \begin{array}{c} \chi' \\ \text{---} \text{---} \text{---} \chi_1 \text{---} \chi \\ \text{---} \text{---} \text{---} \chi' \\ \Phi \\ \text{---} \text{---} \text{---} \chi \\ \text{---} \text{---} \text{---} \chi' \end{array} + \begin{array}{c} \chi' \\ \text{---} \text{---} \text{---} \chi \\ \text{---} \text{---} \text{---} \chi' \\ \Phi \\ \text{---} \text{---} \text{---} \chi \\ \text{---} \text{---} \text{---} \chi_1 \text{---} \chi \end{array} \right\}$$

FIG. 7. The irreducible self energy is obtained by attaching the open tunneling line of ϕ and ϕ^* to the upper and lower propagator.

$$\begin{aligned}
\Phi_{0,0}^{0,\sigma}(\alpha,\sigma,E) &= \text{Diagram 1} \\
&+ \text{Diagram 2} \\
&+ \sum_{\sigma'} \text{Diagram 3}
\end{aligned}$$

FIG. 8. Graphical representation of the self-consistent equation for ϕ beginning with an empty dot state.

$$\begin{aligned}
\Phi_{\sigma,0}^{\sigma,\sigma}(\alpha,\sigma,E) = & \text{Diagram 1} + \text{Diagram 2} + \sum_{\sigma''} \text{Diagram 3} \\
& \text{Diagram 1: A square loop with top horizontal line labeled } \sigma' \rightarrow \sigma \text{ and bottom horizontal line labeled } \sigma' \leftarrow 0. \text{ The right vertical line is labeled } \alpha,\sigma,E. \text{ The loop is labeled } \pi. \text{ A dashed line connects the top-left corner to the bottom-left corner.} \\
& \text{Diagram 2: A rectangular loop with top horizontal line labeled } \sigma' \rightarrow \sigma \text{ and bottom horizontal line labeled } \sigma' \leftarrow 0. \text{ The left vertical line is labeled } \sigma' \leftarrow \sigma. \text{ The right vertical line is labeled } \alpha,\sigma,E. \text{ The loop is labeled } \pi. \text{ A dashed line connects the top-right corner to the bottom-right corner.} \\
& \text{Diagram 3: A rectangular loop with top horizontal line labeled } \sigma' \rightarrow \sigma \text{ and bottom horizontal line labeled } \sigma' \leftarrow 0. \text{ The left vertical line is labeled } \sigma' \leftarrow \sigma. \text{ The right vertical line is labeled } \alpha,\sigma,E. \text{ The loop is labeled } \pi. \text{ A dashed line connects the top-right corner to the bottom-right corner.}
\end{aligned}$$

FIG. 9. Graphical representation of the self-consistent equation for ϕ beginning with an occupied dot state.

$$\begin{aligned}
& \text{Diagram 1: A square loop with top horizontal line labeled } \chi'_1 \rightarrow \chi_1 \text{ and bottom horizontal line labeled } \chi'_2 \leftarrow \chi_2. \text{ The right vertical line is labeled } \pi. \text{ A dashed line connects the top-left corner to the bottom-left corner.} \\
& = \text{Diagram 2: A square loop with top horizontal line labeled } \chi'_1 \rightarrow \chi_1 \text{ and bottom horizontal line labeled } \chi'_2 \leftarrow \chi_2. \text{ The right vertical line is labeled } \pi^{(0)}. \text{ A dashed line connects the top-left corner to the bottom-left corner.} \\
& + \text{Diagram 3: A rectangular loop with top horizontal line labeled } \chi'_1 \rightarrow \chi'_1 \text{ and bottom horizontal line labeled } \chi'_2 \leftarrow \chi'_2. \text{ The left vertical line is labeled } \pi. \text{ The right vertical line is labeled } \sigma. \text{ The loop is labeled } \pi^{(0)}. \text{ A dashed line connects the top-left corner to the bottom-left corner.}
\end{aligned}$$

FIG. 10. The iteration of processes for the propagator π with a tunneling line running in parallel from the right to the left.

$$\sigma^\sigma(E) = \text{Diagram 1} + \sum_{\sigma'} \text{Diagram 2}$$

Diagram 1: A square loop with top horizontal line labeled $\sigma \rightarrow 0$ and bottom horizontal line labeled $0 \leftarrow \sigma$. The right vertical line is labeled E . The loop is labeled σ . A dashed line connects the top-left corner to the bottom-left corner.

Diagram 2: A square loop with top horizontal line labeled $\sigma \rightarrow \sigma$ and bottom horizontal line labeled $0 \leftarrow \sigma'$. The right vertical line is labeled E . The loop is labeled σ' . A dashed line connects the top-left corner to the bottom-left corner.

FIG. 11. In our approximation, the diagram for the irreducible self-energy $\sigma^\sigma(E)$ contains one tunneling line in addition to the backward running line.

$$\begin{aligned}
\bar{G}_\sigma^>(E) = & 2i \text{Im} \left\{ P_0^{\text{st}} \text{Diagram 1} \right. \\
& + \sum_\chi \sum_{\sigma'} P_\chi^{\text{st}} \text{Diagram 2} \left. \right\}
\end{aligned}$$

Diagram 1: A rectangular loop with top horizontal line labeled $0 \rightarrow \sigma$ and bottom horizontal line labeled $0 \leftarrow 0$. The left vertical line is labeled π . The right vertical line is labeled σ,E . A dashed line connects the top-left corner to the bottom-left corner.

Diagram 2: A rectangular loop with top horizontal line labeled $\chi \rightarrow 0$ and bottom horizontal line labeled $\chi \leftarrow \chi$. The left vertical line is labeled Φ^* . The right vertical line is labeled π . The loop is labeled σ' . A dashed line connects the top-left corner to the bottom-left corner.

FIG. 12. Graphical representation of $\bar{G}_\sigma^>(E)$.

$$\begin{aligned}
\bar{G}_\sigma^{<(E)} = & -2i \operatorname{Im} \left\{ P_\sigma^{\text{st}} \right. \\
& + \sum_\chi P_\chi^{\text{st}} \left. \right\}
\end{aligned}$$

FIG. 13. Graphical representation of $\bar{G}_\sigma^{<(E)}$.

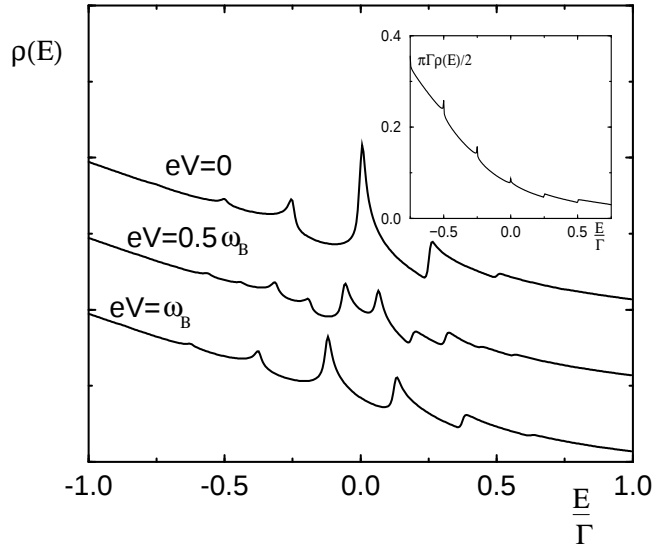


FIG. 14. The spectral density for $M = 2$, $T = T_B = 0.005\Gamma$, $\epsilon = -2\Gamma$, $g = 0.2$, $\omega_B = 0.25\Gamma$ and $E_C = 50\Gamma$ at different voltages. For $V = 0$ there are resonances at multiples of ω_B , which split for finite bias voltage. Inset: spectral density for $M = 1$, $T = 0.00005\Gamma$, $T_B = 0.5\Gamma$, $\epsilon = -\Gamma$, $V = 0$, $g = 0.5$, $\omega_B = 0.25\Gamma$ and $E_C = 50\Gamma$.

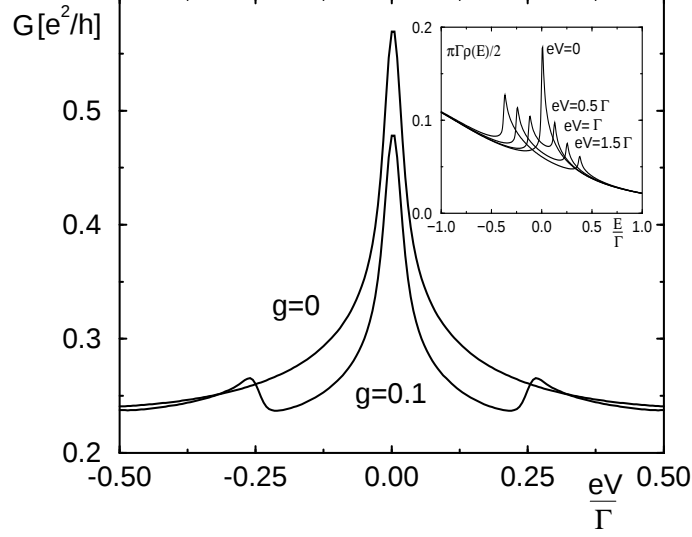


FIG. 15. The differential conductance vs. bias voltage for $T = T_B = 0.005\Gamma$, $\epsilon = -2\Gamma$, $\omega_B = 0.25\Gamma$ and $E_C = 50\Gamma$. The curves show a maximum at zero bias and satellite maxima at multiples of ω_B for a finite electron-boson coupling. Inset ($g = 0$): increasing voltage leads to an overall decrease of the spectral density in the range $|E| < eV$.

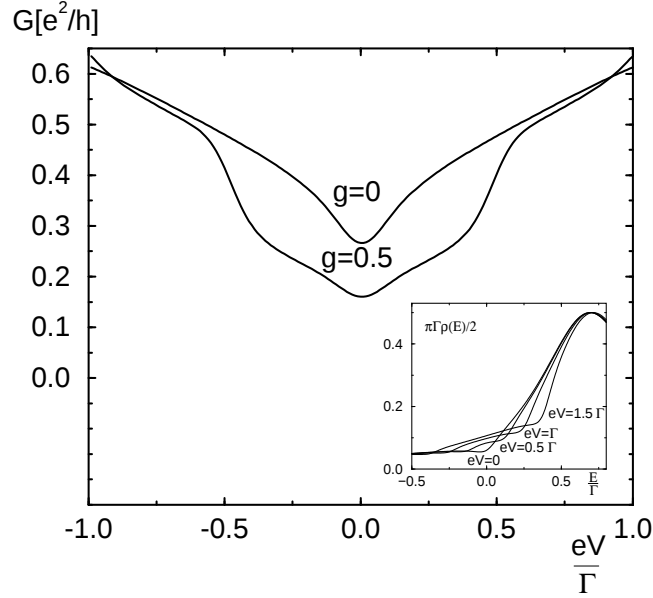


FIG. 16. The differential conductance vs. bias voltage for $T = T_B = 0.025\Gamma$, $\epsilon = 0$, $\omega_B = 0.5\Gamma$ and $E_C = 50\Gamma$. The curves show a minimum at zero bias and steps at multiples of ω_B for a finite electron-boson coupling. Inset ($g = 0$): increasing voltage leads to an overall increase of the spectral density in the range $|E| < eV$.

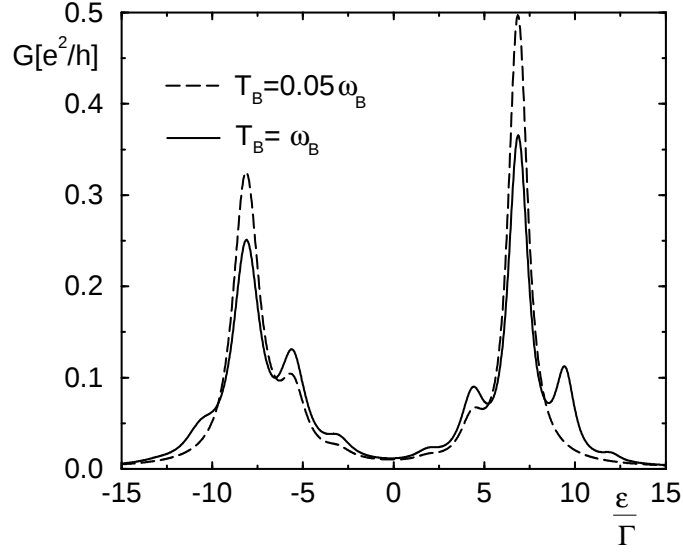


FIG. 17. The differential conductance as a function of ϵ for $T = 0.125\Gamma$, $eV = 15\Gamma$, $g = 0.3$, $\omega_B = 2.5\Gamma$ and $E_C = 250\Gamma$.

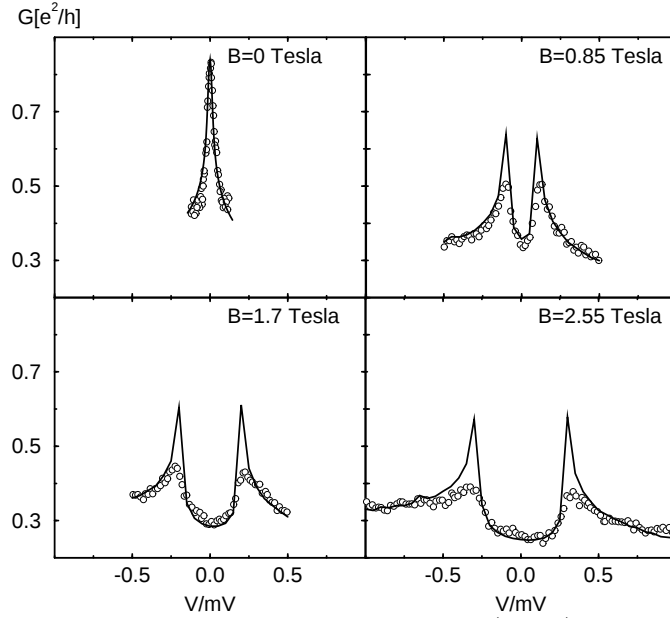


FIG. 18. The differential conductance vs. bias voltage for $T = 4.3\mu eV$, $\epsilon_\sigma(B=0) = -5.2meV$, $\Gamma = 3.4meV$, $a_c = 0.33$, and $E_C = 30meV$. The circles are experimental data from Ref. 24.

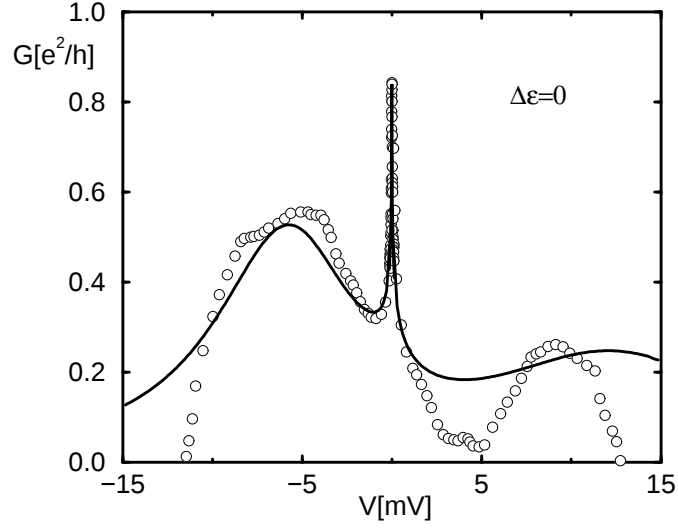


FIG. 19. The differential conductance vs. bias voltage for $T = 4.3\mu\text{eV}$, $\epsilon_\sigma = -5.2\text{meV}$, $B = 0$, $\Gamma = 3.4\text{meV}$, $a_c = 0.33$, and $E_C = 30\text{meV}$. The circles are experimental data from Ref. 24.

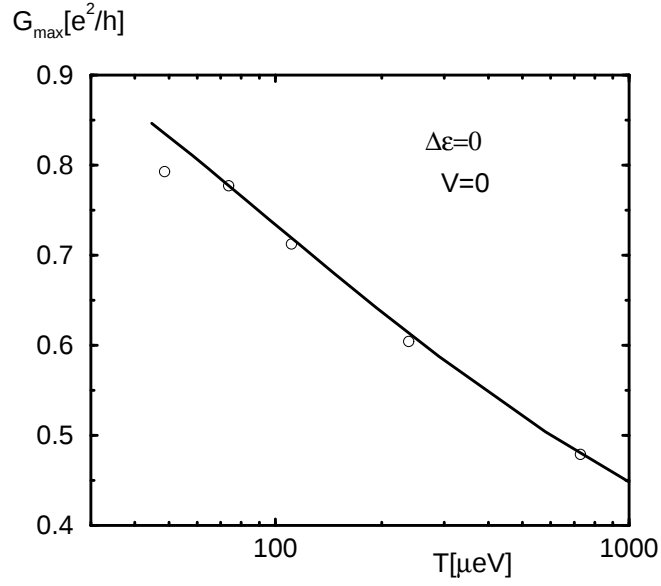


FIG. 20. The maximal linear conductance vs. temperature for $\epsilon_\sigma = -5.2\text{meV}$, $B = 0$, $\Gamma = 3.4\text{meV}$, $a_c = 0.33$, and $E_C = 30\text{meV}$. The circles are experimental data from Ref. 24.

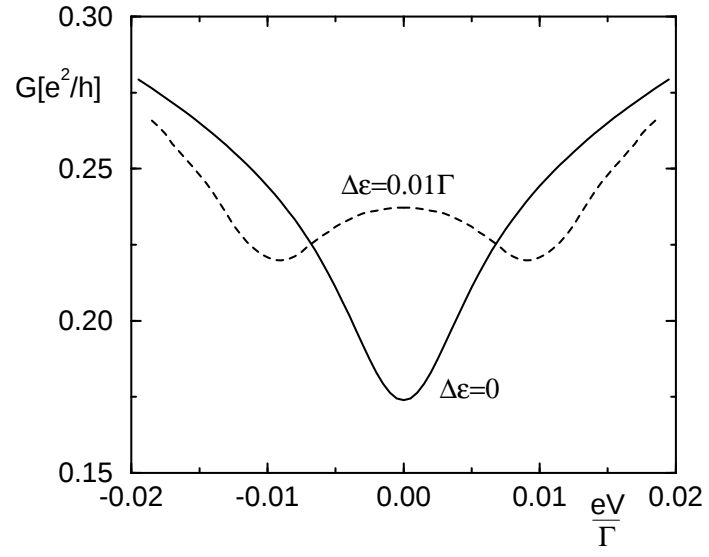


FIG. 21. The differential conductance vs. bias voltage for $T = 0.001\Gamma$, $\epsilon_\sigma = 0.1\Gamma \pm \Delta\epsilon/2$, and $E_C = 10\Gamma$.